

# Si8650/51/52/55 Data Sheet

## Low Power Five-Channel Digital Isolator

Silicon Lab's family of ultra-low-power digital isolators are CMOS devices offering substantial data rate, propagation delay, power, size, reliability, and external BOM advantages over legacy isolation technologies. The operating parameters of these products remain stable across wide temperature ranges and throughout device service life for ease of design and highly uniform performance. All device versions have Schmitt trigger inputs for high noise immunity and only require VDD bypass capacitors.

Data rates up to 150 Mbps are supported, and all devices achieve propagation delays of less than 10 ns. Enable inputs provide a single point control for enabling and disabling output drive. Ordering options include a choice of isolation ratings (1.0, 2.5, 3.75 and 5 kV) and a selectable fail-safe operating mode to control the default output state during power loss. All products >1 kV<sub>RMS</sub> are safety certified by UL, CSA, VDE, and CQC, and products in wide-body packages support reinforced insulation withstanding up to 5 kV<sub>RMS</sub>.

Automotive Grade is available for certain part numbers. These products are built using automotive-specific flows at all steps in the manufacturing process to ensure the robustness and low defectivity required for automotive applications.

### Industrial Applications

- Industrial automation systems
- Medical electronics
- Isolated switch mode supplies
- Isolated ADC, DAC
- Motor control
- Power inverters
- Communication systems

### Automotive Applications

- On-board chargers
- Battery management systems
- Charging stations
- Traction inverters
- Hybrid Electric Vehicles
- Battery Electric Vehicles

### Safety Regulatory Approvals

- UL 1577 recognized
  - Up to 5000 V<sub>RMS</sub> for 1 minute
- CSA component notice 5A approval
  - IEC 60950-1, 62368-1, 60601-1 (reinforced insulation)
- VDE certification conformity
  - VDE 0884-10
  - EN60950-1 (reinforced insulation)
- CQC certification approval
  - GB4943.1

### KEY FEATURES

- High-speed operation
  - DC to 150 Mbps
- No start-up initialization required
- Wide Operating Supply Voltage
  - 2.5–5.5 V
- Up to 5000 V<sub>RMS</sub> isolation
- 60-year life at rated working voltage
- High electromagnetic immunity
- Ultra low power (typical)
  - 5 V Operation
    - 1.6 mA per channel at 1 Mbps
    - 5.5 mA per channel at 100 Mbps
  - 2.5 V Operation
    - 1.5 mA per channel at 1 Mbps
    - 3.5 mA per channel at 100 Mbps
- Tri-state outputs with ENABLE
- Schmitt trigger inputs
- Selectable fail-safe mode
  - Default high or low output (ordering option)
- Precise timing (typical)
  - 10 ns propagation delay
  - 1.5 ns pulse width distortion
  - 0.5 ns channel-channel skew
  - 2 ns propagation delay skew
  - 5 ns minimum pulse width
- Transient Immunity 50 kV/μs
- AEC-Q100 qualification
- Wide temperature range
  - –40 to 125 °C
- RoHS-compliant packages
  - SOIC-16 wide body
  - SOIC-16 narrow body
  - QSOP-16
- Automotive-grade OPNs available
  - AIAG compliant PPAP documentation support
  - IMDS and CAMDS listing support

## 1. Ordering Guide

**Table 1.1. Ordering Guide for Valid OPNs<sup>1, 2, 3</sup>**

| Ordering Part Number (OPN)                                                                                                                                                                                                                                                                                                                                                     | Number of Inputs VDD1 Side | Number of Inputs VDD2 Side | Max Data Rate (Mbps) | Default Output State | Isolation rating (kV) | Temp (°C)     | Package    |
|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|----------------------------|----------------------------|----------------------|----------------------|-----------------------|---------------|------------|
| <b>QSOP-16 Packages</b>                                                                                                                                                                                                                                                                                                                                                        |                            |                            |                      |                      |                       |               |            |
| Si8650BB-B-IU                                                                                                                                                                                                                                                                                                                                                                  | 5                          | 0                          | 150                  | Low                  | 2.5                   | –40 to 125 °C | QSOP-16    |
| Si8650EB-B-IU                                                                                                                                                                                                                                                                                                                                                                  | 5                          | 0                          | 150                  | High                 | 2.5                   | –40 to 125 °C | QSOP-16    |
| Si8651BB-B-IU                                                                                                                                                                                                                                                                                                                                                                  | 4                          | 1                          | 150                  | Low                  | 2.5                   | –40 to 125 °C | QSOP-16    |
| Si8651EB-B-IU                                                                                                                                                                                                                                                                                                                                                                  | 4                          | 1                          | 150                  | High                 | 2.5                   | –40 to 125 °C | QSOP-16    |
| Si8652BB-B-IU                                                                                                                                                                                                                                                                                                                                                                  | 3                          | 2                          | 150                  | Low                  | 2.5                   | –40 to 125 °C | QSOP-16    |
| Si8652EB-B-IU                                                                                                                                                                                                                                                                                                                                                                  | 3                          | 2                          | 150                  | High                 | 2.5                   | –40 to 125 °C | QSOP-16    |
| Si8655BA-B-IU                                                                                                                                                                                                                                                                                                                                                                  | 5                          | 0                          | 150                  | Low                  | 1.0                   | –40 to 125 °C | QSOP-16    |
| Si8655BA-C-IU                                                                                                                                                                                                                                                                                                                                                                  | 5                          | 0                          | 150                  | Low                  | 1.0                   | –40 to 125 °C | QSOP-16    |
| <b>SOIC-16 Packages</b>                                                                                                                                                                                                                                                                                                                                                        |                            |                            |                      |                      |                       |               |            |
| Si8650BB-B-IS1                                                                                                                                                                                                                                                                                                                                                                 | 5                          | 0                          | 150                  | Low                  | 2.5                   | –40 to 125 °C | NB SOIC-16 |
| Si8650BD-B-IS                                                                                                                                                                                                                                                                                                                                                                  | 5                          | 0                          | 150                  | Low                  | 5.0                   | –40 to 125 °C | WB SOIC-16 |
| Si8650EC-B-IS1                                                                                                                                                                                                                                                                                                                                                                 | 5                          | 0                          | 150                  | High                 | 3.75                  | –40 to 125 °C | NB SOIC-16 |
| Si8650ED-B-IS                                                                                                                                                                                                                                                                                                                                                                  | 5                          | 0                          | 150                  | High                 | 5.0                   | –40 to 125 °C | WB SOIC-16 |
| Si8651BB-B-IS1                                                                                                                                                                                                                                                                                                                                                                 | 4                          | 1                          | 150                  | Low                  | 2.5                   | –40 to 125 °C | NB SOIC-16 |
| Si8651BC-B-IS1                                                                                                                                                                                                                                                                                                                                                                 | 4                          | 1                          | 150                  | Low                  | 3.75                  | –40 to 125 °C | NB SOIC-16 |
| Si8651BD-B-IS                                                                                                                                                                                                                                                                                                                                                                  | 4                          | 1                          | 150                  | Low                  | 5.0                   | –40 to 125 °C | WB SOIC-16 |
| Si8651EC-B-IS1                                                                                                                                                                                                                                                                                                                                                                 | 4                          | 1                          | 150                  | High                 | 3.75                  | –40 to 125 °C | NB SOIC-16 |
| Si8651ED-B-IS                                                                                                                                                                                                                                                                                                                                                                  | 4                          | 1                          | 150                  | High                 | 5.0                   | –40 to 125 °C | WB SOIC-16 |
| Si8652BB-B-IS1                                                                                                                                                                                                                                                                                                                                                                 | 3                          | 2                          | 150                  | Low                  | 2.5                   | –40 to 125 °C | NB SOIC-16 |
| Si8652BC-B-IS1                                                                                                                                                                                                                                                                                                                                                                 | 3                          | 2                          | 150                  | Low                  | 3.75                  | –40 to 125 °C | NB SOIC-16 |
| Si8652BD-B-IS                                                                                                                                                                                                                                                                                                                                                                  | 3                          | 2                          | 150                  | Low                  | 5.0                   | –40 to 125 °C | WB SOIC-16 |
| Si8652EC-B-IS1                                                                                                                                                                                                                                                                                                                                                                 | 3                          | 2                          | 150                  | High                 | 3.75                  | –40 to 125 °C | NB SOIC-16 |
| Si8652ED-B-IS                                                                                                                                                                                                                                                                                                                                                                  | 3                          | 2                          | 150                  | High                 | 5.0                   | –40 to 125 °C | WB SOIC-16 |
| Si8655BA-B-IS                                                                                                                                                                                                                                                                                                                                                                  | 5                          | 0                          | 150                  | Low                  | 1.0                   | –40 to 125 °C | WB SOIC-16 |
| Si8655BB-B-IS1                                                                                                                                                                                                                                                                                                                                                                 | 5                          | 0                          | 150                  | Low                  | 2.5                   | –40 to 125 °C | NB SOIC-16 |
| Si8655BD-B-IS                                                                                                                                                                                                                                                                                                                                                                  | 5                          | 0                          | 150                  | Low                  | 5.0                   | –40 to 125 °C | WB SOIC-16 |
| <b>Notes:</b> <ol style="list-style-type: none"> <li>1. All packages are RoHS-compliant with peak reflow temperatures of 260 °C according to the JEDEC industry standard classifications and peak solder temperatures.</li> <li>2. “Si” and “SI” are used interchangeably.</li> <li>3. An “R” at the end of the part number denotes tape and reel packaging option.</li> </ol> |                            |                            |                      |                      |                       |               |            |

## Automotive Grade OPNs

Automotive-grade devices are built using automotive-specific flows at all steps in the manufacturing process to ensure robustness and low defectivity. These devices are supported with AIAG-compliant Production Part Approval Process (PPAP) documentation, and feature International Material Data System (IMDS) and China Automotive Material Data System (CAMDS) listing. Qualifications are compliant with AEC-Q100, and a zero-defect methodology is maintained throughout definition, design, evaluation, qualification, and mass production steps.

**Table 1.2. Ordering Guide for Automotive Grade OPNs<sup>1, 2, 4, 5</sup>**

| Ordering Part Number (OPN)                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                  | Number of Inputs VDD1 Side | Number of Inputs VDD2 Side | Max Data Rate (Mbps) | Default Output State | Isolation rating (kV) | Temp (°C)     | Package    |
|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|----------------------------|----------------------------|----------------------|----------------------|-----------------------|---------------|------------|
| <b>QSOP-16 Packages</b>                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                     |                            |                            |                      |                      |                       |               |            |
| Si8655BA-AU                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                 | 5                          | 0                          | 150                  | Low                  | 1.0                   | –40 to 125 °C | QSOP-16    |
| <b>SOIC-16 Packages</b>                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                     |                            |                            |                      |                      |                       |               |            |
| Si8651BB-AS1                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                | 4                          | 1                          | 150                  | Low                  | 2.5                   | –40 to 125 °C | NB SOIC-16 |
| Si8651BD-AS                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                 | 4                          | 1                          | 150                  | Low                  | 5.0                   | –40 to 125 °C | WB SOIC-16 |
| Si8652BD-AS                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                 | 3                          | 2                          | 150                  | Low                  | 5.0                   | –40 to 125 °C | WB SOIC-16 |
| Si8655BA-AS                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                 | 5                          | 0                          | 150                  | Low                  | 1.0                   | –40 to 125 °C | WB SOIC-16 |
| <b>Note:</b> <ol style="list-style-type: none"> <li>1. All packages are RoHS-compliant with peak reflow temperatures of 260 °C according to the JEDEC industry standard classifications.</li> <li>2. “Si” and “SI” are used interchangeably.</li> <li>3. An “R” at the end of the part number denotes tape and reel packaging option.</li> <li>4. Automotive-Grade devices (with an “-A” suffix) are identical in construction materials, topside marking, and electrical parameters to their Industrial-Grade (with a “-I” suffix) version counterparts. Automotive-Grade products are produced utilizing full automotive process flows and additional statistical process controls throughout the manufacturing flow. The Automotive-Grade part number is included on shipping labels.</li> <li>5. Additional Ordering Part Numbers may be available in Automotive-Grade. Please contact your local Silicon Labs sales representative for further information.</li> </ol> |                            |                            |                      |                      |                       |               |            |

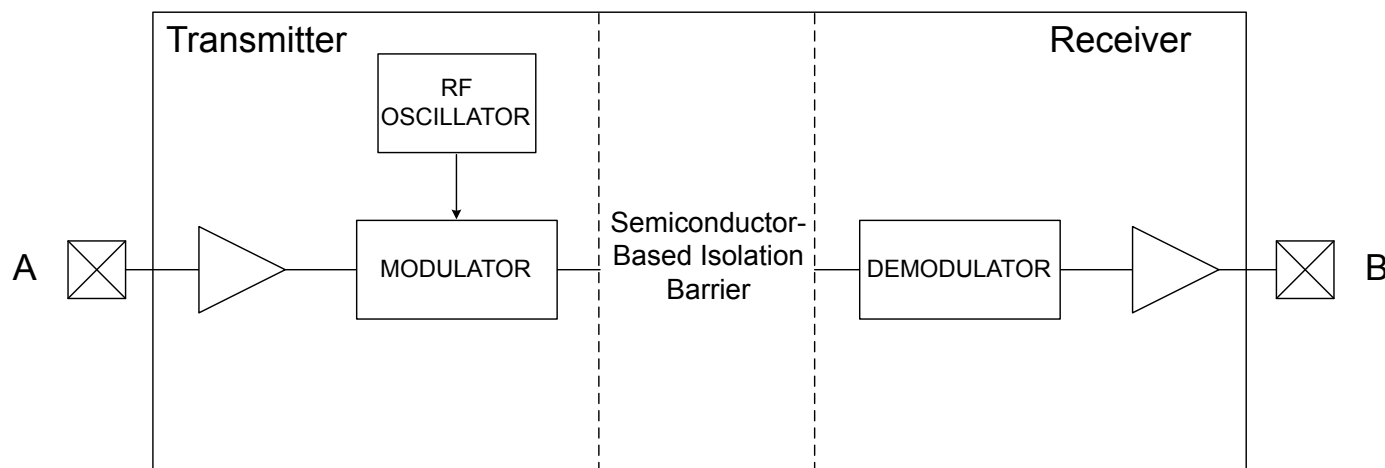
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## 2. Functional Description

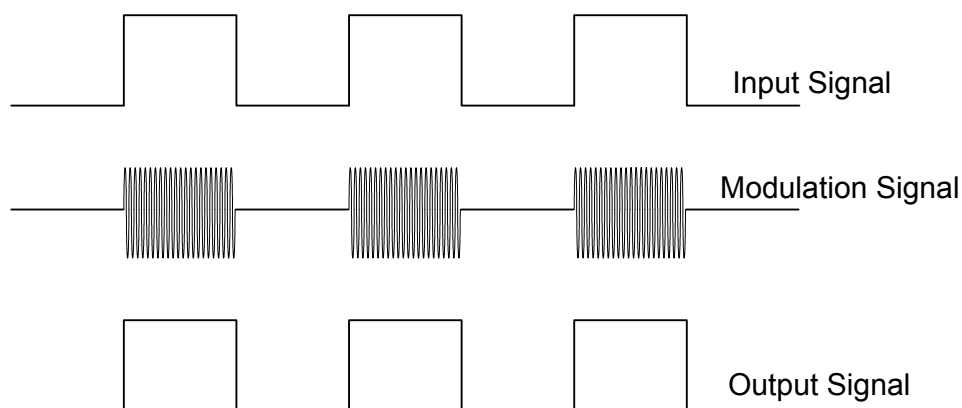
### 2.1 Theory of Operation

The operation of an Si865x channel is analogous to that of an opto coupler, except an RF carrier is modulated instead of light. This simple architecture provides a robust isolated data path and requires no special considerations or initialization at start-up. A simplified block diagram for a single Si865x channel is shown in the figure below.



**Figure 2.1. Simplified Channel Diagram**

A channel consists of an RF Transmitter and RF Receiver separated by a semiconductor-based isolation barrier. Referring to the Transmitter, input A modulates the carrier provided by an RF oscillator using on/off keying. The Receiver contains a demodulator that decodes the input state according to its RF energy content and applies the result to output B via the output driver. This RF on/off keying scheme is superior to pulse code schemes as it provides best-in-class noise immunity, low power consumption, and better immunity to magnetic fields. See the figure below for more details.



**Figure 2.2. Modulation Scheme**

## 2.2 Eye Diagram

The figure below illustrates an eye-diagram taken on an Si8650. For the data source, the test used an Anritsu (MP1763C) Pulse Pattern Generator set to 1000 ns/div. The output of the generator's clock and data from an Si8650 were captured on an oscilloscope. The results illustrate that data integrity was maintained even at the high data rate of 150 Mbps. The results also show that 2 ns pulse width distortion and 350 ps peak jitter were exhibited.

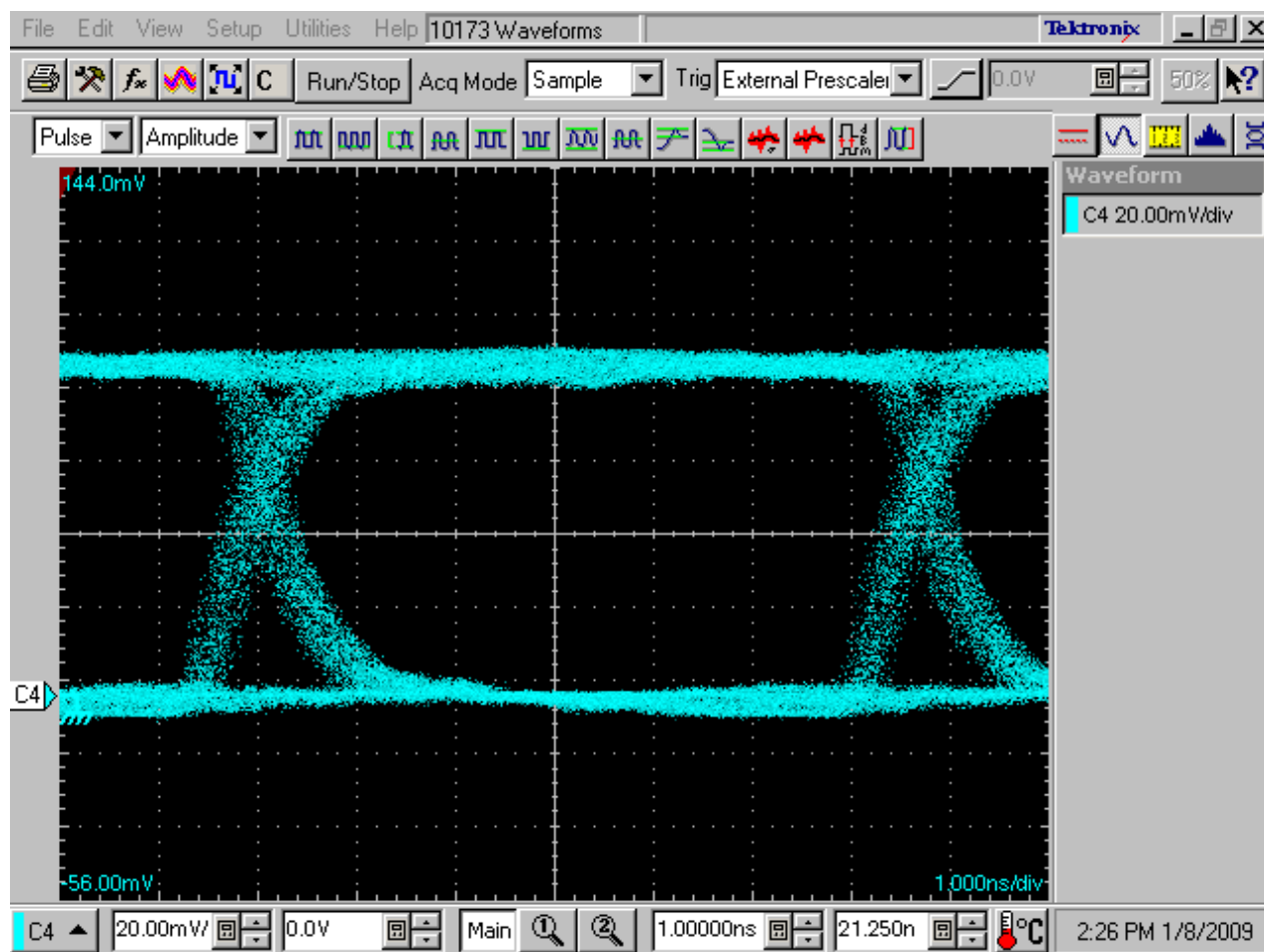


Figure 2.3. Eye Diagram

### 3. Device Operation

Device behavior during start-up, normal operation, and shutdown is shown in [Figure 3.1 Device Behavior during Normal Operation on page 9](#), where UVLO+ and UVLO- are the positive-going and negative-going thresholds respectively. Refer to the table below to determine outputs when power supply (VDD) is not present. Additionally, refer to the table on the following page for logic conditions when enable pins are used.

**Table 3.1. Si865x Logic Operation**

| V <sub>I</sub> Input <sup>1,2</sup> | EN Input <sup>1,2,3,4</sup> | VDDI State <sup>1,5,6</sup> | VDDO State <sup>1,5,6</sup> | V <sub>O</sub> Output <sup>1,2</sup> | Comments                                                                                                                                                                                                                                                                   |
|-------------------------------------|-----------------------------|-----------------------------|-----------------------------|--------------------------------------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| H                                   | H or NC                     | P                           | P                           | H                                    | Enabled, normal operation.                                                                                                                                                                                                                                                 |
| L                                   | H or NC                     | P                           | P                           | L                                    |                                                                                                                                                                                                                                                                            |
| X <sup>7</sup>                      | L                           | P                           | P                           | Hi-Z <sup>8</sup>                    | Disabled.                                                                                                                                                                                                                                                                  |
| X <sup>7</sup>                      | H or NC                     | UP                          | P                           | L <sup>9</sup><br>H <sup>9</sup>     | Upon transition of VDDI from unpowered to powered, V <sub>O</sub> returns to the same state as V <sub>I</sub> in less than 1 μs.                                                                                                                                           |
| X <sup>7</sup>                      | L                           | UP                          | P                           | Hi-Z <sup>8</sup>                    | Disabled.                                                                                                                                                                                                                                                                  |
| X <sup>7</sup>                      | X <sup>7</sup>              | P                           | UP                          | Undetermined                         | Upon transition of VDDO from unpowered to powered, V <sub>O</sub> returns to the same state as V <sub>I</sub> within 1 μs, if EN is in either the H or NC state. Upon transition of VDDO from unpowered to powered, V <sub>O</sub> returns to Hi-Z within 1 μs if EN is L. |

**Notes:**

1. VDDI and VDDO are the input and output power supplies. V<sub>I</sub> and V<sub>O</sub> are the respective input and output terminals. EN is the enable control input located on the same output side.
2. X = not applicable; H = Logic High; L = Logic Low; Hi-Z = High Impedance.
3. It is recommended that the enable inputs be connected to an external logic high or low level when the Si865x is operating in noisy environments.
4. No Connect (NC) replaces EN1 on Si8650. No Connects are not internally connected and can be left floating, tied to VDD, or tied to GND.
5. "Powered" state (P) is defined as 2.5 V < VDD < 5.5 V.
6. "Unpowered" state (UP) is defined as VDD = 0 V.
7. Note that an I/O can power the die for a given side through an internal diode if its source has adequate current.
8. When using the enable pin (EN) function, the output pin state is driven into a high-impedance state when the EN pin is disabled (EN = 0).
9. See [1. Ordering Guide](#) for details. This is the selectable fail-safe operating mode (ordering option). Some devices have default output state = H, and some have default output state = L, depending on the ordering part number (OPN). For default high devices, the data channels have pull-ups on inputs/outputs. For default low devices, the data channels have pull-downs on inputs/outputs.

Table 3.2. Enable Input Truth <sup>1</sup>

| P/N    | EN1 <sup>1,2</sup> | EN2 <sup>1,2</sup> | Operation                                                                                      |
|--------|--------------------|--------------------|------------------------------------------------------------------------------------------------|
| Si8650 | —                  | H                  | Outputs B1, B2, B3, B4, B5 are enabled and follow input state.                                 |
|        | —                  | L                  | Outputs B1, B2, B3, B4, B5 are disabled and Logic Low or in high impedance state. <sup>3</sup> |
| Si8651 | H                  | X                  | Output A5 enabled and follow input state.                                                      |
|        | L                  | X                  | Output A5 disabled and in high impedance state. <sup>3</sup>                                   |
|        | X                  | H                  | Outputs B1, B2, B3, B4 are enabled and follow input state.                                     |
|        | X                  | L                  | Outputs B1, B2, B3, B4 are disabled and in high impedance state. <sup>3</sup>                  |
| Si8652 | H                  | X                  | Outputs A4 and A5 are enabled and follow input state.                                          |
|        | L                  | X                  | Outputs A4 and A5 are disabled and in high impedance state. <sup>3</sup>                       |
|        | X                  | H                  | Outputs B1, B2, B3 are enabled and follow input state.                                         |
|        | X                  | L                  | Outputs B1, B2, B3 are disabled and in high impedance state. <sup>3</sup>                      |
| Si8655 | —                  | —                  | Outputs B1, B2, B3, B4, B5 are enabled and follow input state.                                 |

**Notes:**

1. Enable inputs EN1 and EN2 can be used for multiplexing, for clock sync, or other output control. These inputs are internally pulled-up to local VDD by a 2  $\mu$ A current source allowing them to be connected to an external logic level (high or low) or left floating. To minimize noise coupling, do not connect circuit traces to EN1 or EN2 if they are left floating. If EN1, EN2 are unused, it is recommended they be connected to an external logic level, especially if the Si865x is operating in a noisy environment.
2. X = not applicable; H = Logic High; L = Logic Low.
3. When using the enable pin (EN) function, the output pin state is driven into a high-impedance state when the EN pin is disabled (EN = 0).

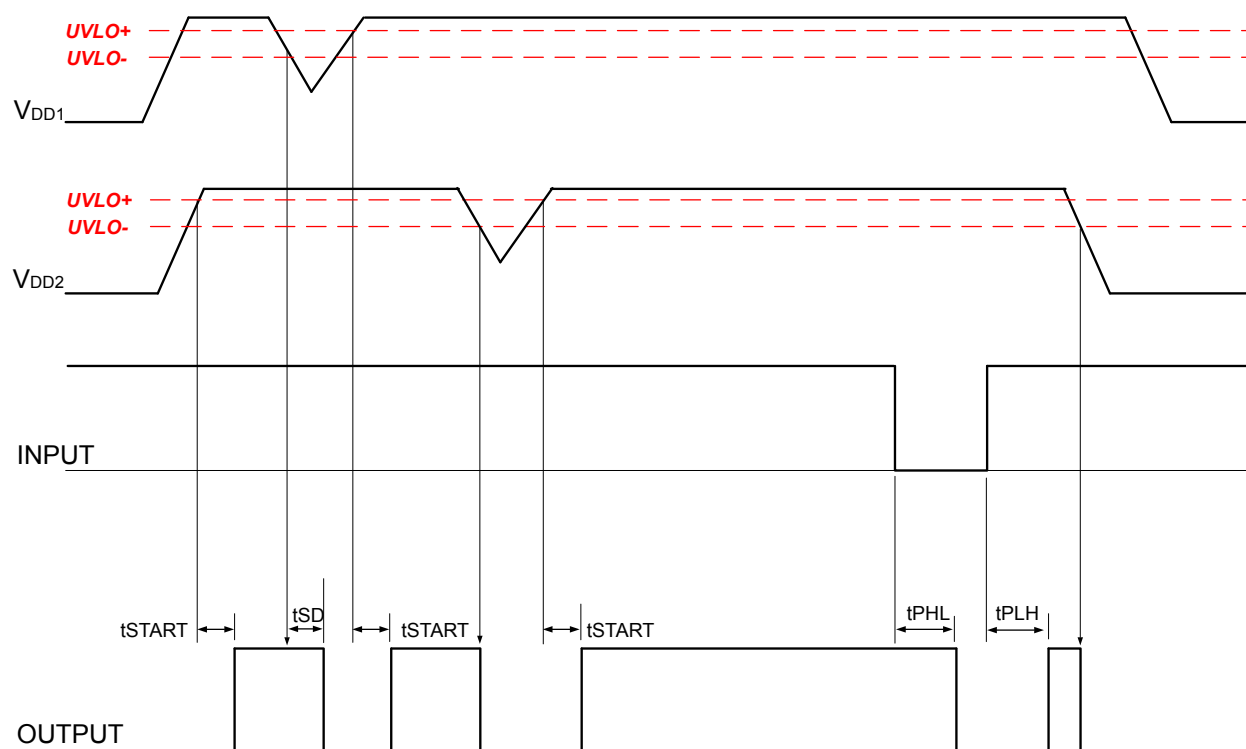
**3.1 Device Startup**

Outputs are held low during powerup until VDD is above the UVLO threshold for time period tSTART. Following this, the outputs follow the states of inputs.

**3.2 Undervoltage Lockout**

Undervoltage Lockout (UVLO) is provided to prevent erroneous operation during device startup and shutdown or when VDD is below its specified operating circuits range. Both Side A and Side B each have their own undervoltage lockout monitors. Each side can enter or exit UVLO independently. For example, Side A unconditionally enters UVLO when  $V_{DD1}$  falls below  $V_{DD1(UVLO-)}$  and exits UVLO when  $V_{DD1}$  rises above  $V_{DD1(UVLO+)}$ . Side B operates the same as Side A with respect to its  $V_{DD2}$  supply.





**Figure 3.1. Device Behavior during Normal Operation**

### 3.3 Layout Recommendations

To ensure safety in the end user application, high voltage circuits (i.e., circuits with  $>30\text{ V}_{AC}$ ) must be physically separated from the safety extra-low voltage circuits (SELV is a circuit with  $<30\text{ V}_{AC}$ ) by a certain distance (creepage/clearance). If a component, such as a digital isolator, straddles this isolation barrier, it must meet those creepage/clearance requirements and also provide a sufficiently large high-voltage breakdown protection rating (commonly referred to as working voltage protection). [Table 4.5 Regulatory Information<sup>1</sup> on page 21](#) and [Table 4.6 Insulation and Safety-Related Specifications on page 22](#) detail the working voltage and creepage/clearance capabilities of the Si86xx. These tables also detail the component standards (UL1577, IEC60747, CSA 5A), which are readily accepted by certification bodies to provide proof for end-system specifications requirements. Refer to the end-system specification (61010-1, 60950-1, 60601-1, etc.) requirements before starting any design that uses a digital isolator.

#### 3.3.1 Supply Bypass

The Si865x family requires a  $0.1\text{ }\mu\text{F}$  bypass capacitor between  $V_{DD1}$  and GND1 and  $V_{DD2}$  and GND2. The capacitor should be placed as close as possible to the package. To enhance the robustness of a design, the user may also include resistors ( $50\text{--}300\text{ }\Omega$ ) in series with the inputs and outputs if the system is excessively noisy.

#### 3.3.2 Output Pin Termination

The nominal output impedance of an isolator driver channel is approximately  $50\text{ }\Omega$ ,  $\pm 40\%$ , which is a combination of the value of the on-chip series termination resistor and channel resistance of the output driver FET. When driving loads where transmission line effects will be a factor, output pins should be appropriately terminated with controlled impedance PCB traces.

### 3.4 Fail-Safe Operating Mode

Si86xx devices feature a selectable (by ordering option) mode whereby the default output state (when the input supply is unpowered) can either be a logic high or logic low when the output supply is powered. See [Table 3.1 Si865x Logic Operation on page 7](#) and [1. Ordering Guide](#) for more information.

### 3.5 Typical Performance Characteristics

The typical performance characteristics depicted in the following diagrams are for information purposes only. Refer to [Table 4.2 Electrical Characteristics on page 12](#) through [Table 4.4 Electrical Characteristics on page 18](#) for actual specification limits.

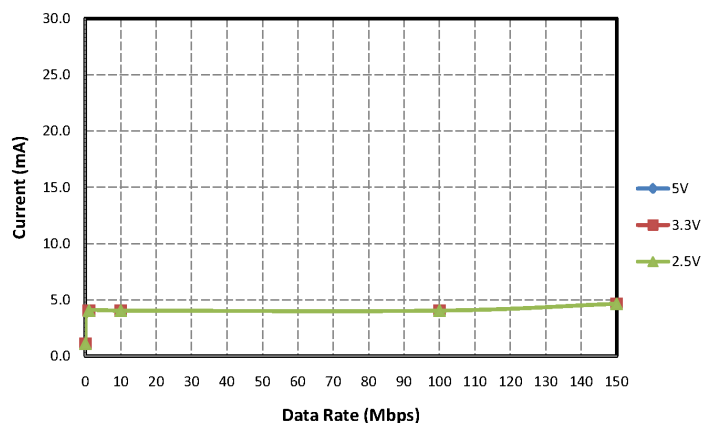


Figure 3.2. Si8650/55 Typical  $V_{DD1}$  Supply Current vs. Data Rate 5, 3.3, and 2.5 V Operation

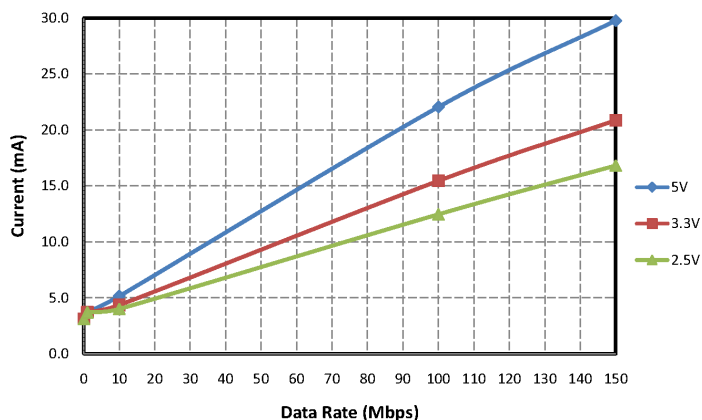


Figure 3.3. Si8650/55 Typical  $V_{DD2}$  Supply Current vs. Data Rate 5, 3.3, and 2.5 V Operation (15 pF Load)

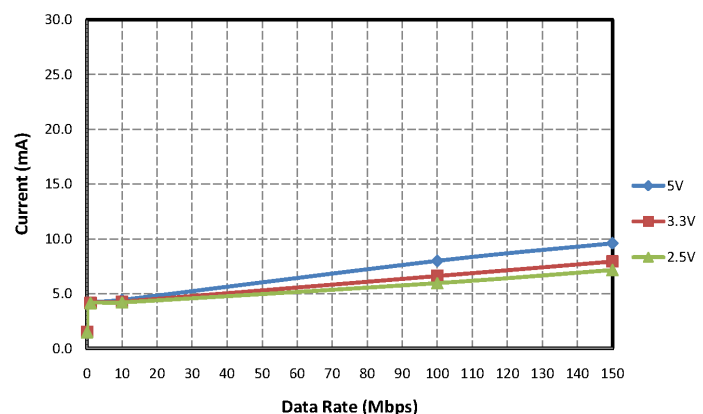


Figure 3.4. Si8651 Typical  $V_{DD1}$  Supply Current vs. Data Rate 5, 3.3, and 2.5 V Operation (15 pF Load)

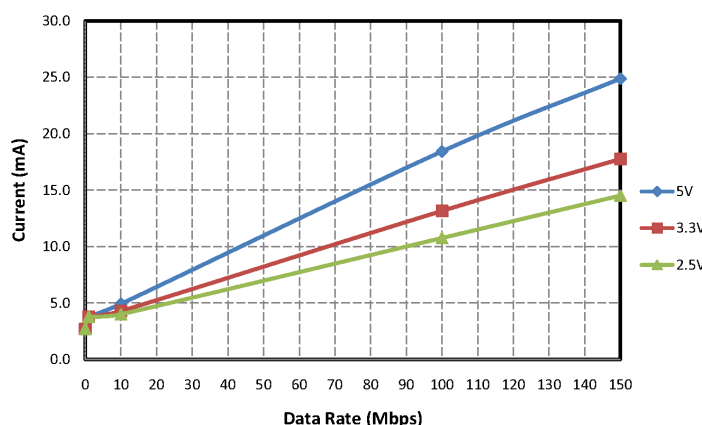


Figure 3.5. Si8651 Typical  $V_{DD2}$  Supply Current vs. Data Rate 5, 3.3, and 2.5 V Operation (15 pF Load)

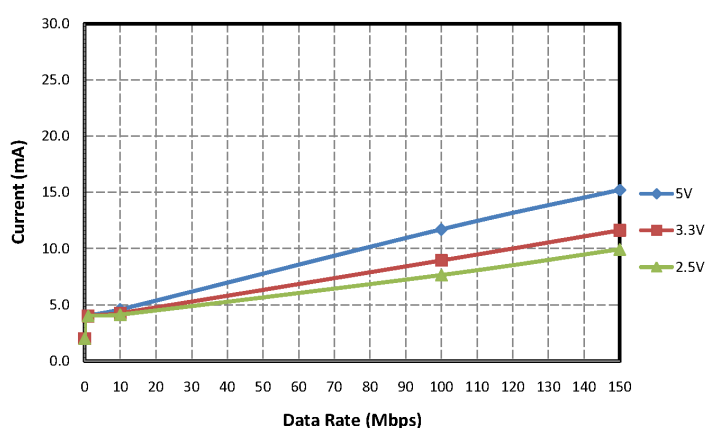


Figure 3.6. Si8652 Typical  $V_{DD1}$  Supply Current vs. Data Rate 5, 3.3, and 2.5 V Operation (15 pF Load)

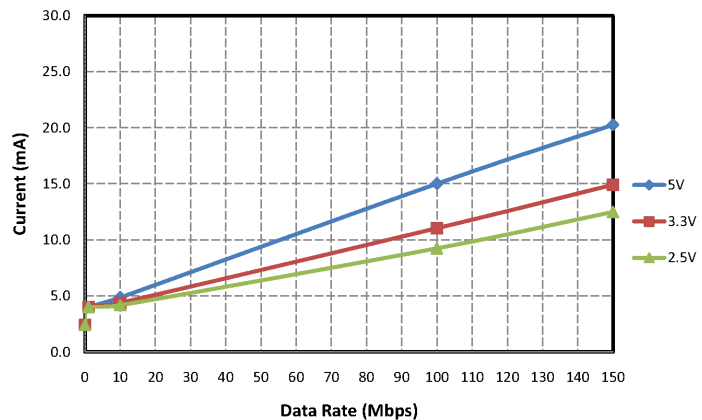
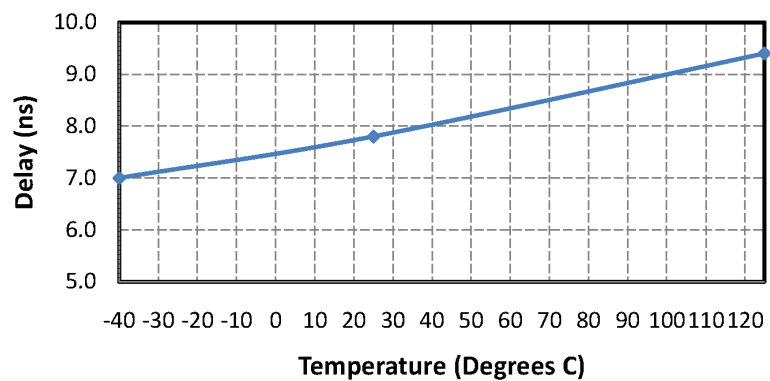


Figure 3.7. Si8652 Typical  $V_{DD2}$  Supply Current vs. Data Rate 5, 3.3, and 2.5 V Operation (15 pF Load)



**Figure 3.8. Propagation Delay  
vs. Temperature**

## 4. Electrical Specifications

**Table 4.1. Recommended Operating Conditions**

| Parameter                                  | Symbol    | Min   | Typ | Max | Unit |
|--------------------------------------------|-----------|-------|-----|-----|------|
| Junction Operating Temperature             | $T_J$     | —     | —   | 150 | °C   |
| Ambient Operating Temperature <sup>1</sup> | $T_A$     | −40   | 25  | 125 | °C   |
| Supply Voltage                             | $V_{DD1}$ | 2.375 | —   | 5.5 | V    |
|                                            | $V_{DD2}$ | 2.375 | —   | 5.5 | V    |

**Note:**

1. The maximum ambient temperature is dependent on data frequency, output loading, number of operating channels, and supply voltage.

**Table 4.2. Electrical Characteristics**

( $V_{DD1} = 5\text{ V} \pm 10\%$ ,  $V_{DD2} = 5\text{ V} \pm 10\%$ ,  $T_A = -40$  to  $125\text{ }^{\circ}\text{C}$ )

| Parameter                      | Symbol    | Test Condition                | Min                      | Typ  | Max      | Unit          |
|--------------------------------|-----------|-------------------------------|--------------------------|------|----------|---------------|
| VDD Undervoltage Threshold     | VDDUV+    | $V_{DD1}$ , $V_{DD2}$ rising  | 1.95                     | 2.24 | 2.375    | V             |
| VDD Undervoltage Threshold     | VDDUV−    | $V_{DD1}$ , $V_{DD2}$ falling | 1.88                     | 2.16 | 2.325    | V             |
| VDD Undervoltage Hysteresis    | VDDHYS    |                               | 50                       | 70   | 95       | mV            |
| Positive-Going Input Threshold | VT+       | All inputs rising             | 1.4                      | 1.67 | 1.9      | V             |
| Negative-Going Input Threshold | VT−       | All inputs falling            | 1.0                      | 1.23 | 1.4      | V             |
| Input Hysteresis               | $V_{HYS}$ |                               | 0.38                     | 0.44 | 0.50     | V             |
| High Level Input Voltage       | $V_{IH}$  |                               | 2.0                      | —    | —        | V             |
| Low Level input voltage        | $V_{IL}$  |                               | —                        | —    | 0.8      | V             |
| High Level Output Voltage      | $V_{OH}$  | $I_{OH} = -4\text{ mA}$       | $V_{DD1}, V_{DD2} - 0.4$ | 4.8  | —        | V             |
| Low Level Output Voltage       | $V_{OL}$  | $I_{OL} = 4\text{ mA}$        | —                        | 0.2  | 0.4      | V             |
| Input Leakage Current          | $I_L$     |                               | —                        | —    | $\pm 10$ | $\mu\text{A}$ |
| Output Impedance <sup>1</sup>  | $Z_O$     |                               | —                        | 50   | —        | $\Omega$      |
| Enable Input High Current      | $I_{ENH}$ | $V_{ENx} = V_{IH}$            | —                        | 2.0  | —        | $\mu\text{A}$ |
| Enable Input Low Current       | $I_{ENL}$ | $V_{ENx} = V_{IL}$            | —                        | 2.0  | —        | $\mu\text{A}$ |

**DC Supply Current (All Inputs 0 V or at Supply)**

|                               |  |                                    |   |     |     |    |
|-------------------------------|--|------------------------------------|---|-----|-----|----|
| <b>Si8650Bx, Ex, Si8655Bx</b> |  |                                    |   |     |     |    |
| $V_{DD1}$                     |  | $V_I = 0(\text{Bx}), 1(\text{Ex})$ | — | 1.1 | 1.8 | mA |
| $V_{DD2}$                     |  | $V_I = 0(\text{Bx}), 1(\text{Ex})$ | — | 3.1 | 4.7 |    |
| $V_{DD1}$                     |  | $V_I = 1(\text{Bx}), 0(\text{Ex})$ | — | 7.0 | 9.8 |    |
| $V_{DD2}$                     |  | $V_I = 1(\text{Bx}), 0(\text{Ex})$ | — | 3.3 | 5.0 |    |

| Parameter                                                                                   | Symbol | Test Condition       | Min | Typ  | Max  | Unit |
|---------------------------------------------------------------------------------------------|--------|----------------------|-----|------|------|------|
| <b>Si8651Bx, Ex</b>                                                                         |        |                      |     |      |      |      |
| $V_{DD1}$                                                                                   |        | $V_I = 0(Bx), 1(Ex)$ | —   | 1.5  | 2.4  | mA   |
| $V_{DD2}$                                                                                   |        | $V_I = 0(Bx), 1(Ex)$ | —   | 2.7  | 4.1  |      |
| $V_{DD1}$                                                                                   |        | $V_I = 1(Bx), 0(Ex)$ | —   | 6.6  | 9.2  |      |
| $V_{DD2}$                                                                                   |        | $V_I = 1(Bx), 0(Ex)$ | —   | 4.0  | 6.0  |      |
| <b>Si8652Bx, Ex</b>                                                                         |        |                      |     |      |      |      |
| $V_{DD1}$                                                                                   |        | $V_I = 0(Bx), 1(Ex)$ | —   | 2.0  | 3.0  | mA   |
| $V_{DD2}$                                                                                   |        | $V_I = 0(Bx), 1(Ex)$ | —   | 2.4  | 3.6  |      |
| $V_{DD1}$                                                                                   |        | $V_I = 1(Bx), 0(Ex)$ | —   | 5.6  | 7.8  |      |
| $V_{DD2}$                                                                                   |        | $V_I = 1(Bx), 0(Ex)$ | —   | 5.0  | 7.5  |      |
| <b>1 Mbps Supply Current (All Inputs = 500 kHz Square Wave, CI = 15 pF on All Outputs)</b>  |        |                      |     |      |      |      |
| <b>Si8650Bx, Ex, Si8655Bx</b>                                                               |        |                      |     |      |      |      |
| $V_{DD1}$                                                                                   |        |                      | —   | 4.1  | 5.7  | mA   |
| $V_{DD2}$                                                                                   |        |                      | —   | 3.7  | 5.2  |      |
| <b>Si8651Bx, Ex</b>                                                                         |        |                      |     |      |      |      |
| $V_{DD1}$                                                                                   |        |                      | —   | 4.2  | 5.8  | mA   |
| $V_{DD2}$                                                                                   |        |                      | —   | 3.8  | 5.3  |      |
| <b>Si8652Bx, Ex</b>                                                                         |        |                      |     |      |      |      |
| $V_{DD1}$                                                                                   |        |                      | —   | 4.0  | 5.6  | mA   |
| $V_{DD2}$                                                                                   |        |                      | —   | 4.0  | 5.6  |      |
| <b>10 Mbps Supply Current (All Inputs = 5 MHz Square Wave, CI = 15 pF on All Outputs)</b>   |        |                      |     |      |      |      |
| <b>Si8650Bx, Ex, Si8655Bx</b>                                                               |        |                      |     |      |      |      |
| $V_{DD1}$                                                                                   |        |                      | —   | 4.1  | 5.7  | mA   |
| $V_{DD2}$                                                                                   |        |                      | —   | 5.2  | 7.2  |      |
| <b>Si8651Bx, Ex</b>                                                                         |        |                      |     |      |      |      |
| $V_{DD1}$                                                                                   |        |                      | —   | 4.4  | 6.2  | mA   |
| $V_{DD2}$                                                                                   |        |                      | —   | 4.9  | 6.9  |      |
| <b>Si8652Bx, Ex</b>                                                                         |        |                      |     |      |      |      |
| $V_{DD1}$                                                                                   |        |                      | —   | 4.6  | 6.4  | mA   |
| $V_{DD2}$                                                                                   |        |                      | —   | 4.9  | 6.8  |      |
| <b>100 Mbps Supply Current (All Inputs = 50 MHz Square Wave, CI = 15 pF on All Outputs)</b> |        |                      |     |      |      |      |
| <b>Si8650Bx, Ex, Si8655Bx</b>                                                               |        |                      |     |      |      |      |
| $V_{DD1}$                                                                                   |        |                      | —   | 4.1  | 5.7  | mA   |
| $V_{DD2}$                                                                                   |        |                      | —   | 22.1 | 28.7 |      |
| <b>Si8651Bx, Ex</b>                                                                         |        |                      |     |      |      |      |

| Parameter                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                           | Symbol             | Test Condition                                                                                                                                               | Min | Typ  | Max  | Unit        |
|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--------------------|--------------------------------------------------------------------------------------------------------------------------------------------------------------|-----|------|------|-------------|
| $V_{DD1}$                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                           |                    |                                                                                                                                                              | —   | 8.0  | 10.8 | mA          |
| $V_{DD2}$                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                           |                    |                                                                                                                                                              | —   | 18.4 | 24   |             |
| <b>Si8652Bx, Ex</b>                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                 |                    |                                                                                                                                                              |     |      |      |             |
| $V_{DD1}$                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                           |                    |                                                                                                                                                              | —   | 11.7 | 15.2 | mA          |
| $V_{DD2}$                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                           |                    |                                                                                                                                                              | —   | 15   | 19.5 |             |
| <b>Timing Characteristics</b>                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                       |                    |                                                                                                                                                              |     |      |      |             |
| <b>Si865xBx, Ex</b>                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                 |                    |                                                                                                                                                              |     |      |      |             |
| Maximum Data Rate                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                   |                    |                                                                                                                                                              | 0   | —    | 150  | Mbps        |
| Minimum Pulse Width                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                 |                    |                                                                                                                                                              | —   | —    | 5.0  | ns          |
| Propagation Delay                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                   | $t_{PHL}, t_{PLH}$ | See <a href="#">Figure 4.2 Propagation Delay Timing on page 15</a>                                                                                           | 5.0 | 8.0  | 13   | ns          |
| Pulse Width Distortion<br>$ t_{PLH} - t_{PHL} $                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                     | PWD                | See <a href="#">Figure 4.2 Propagation Delay Timing on page 15</a>                                                                                           | —   | 0.2  | 4.5  | ns          |
| Propagation Delay Skew <sup>2</sup>                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                 | $t_{PSK(P-P)}$     |                                                                                                                                                              | —   | 2.0  | 4.5  | ns          |
| Channel-Channel Skew                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                | $t_{PSK}$          |                                                                                                                                                              | —   | 0.4  | 2.5  | ns          |
| <b>All Models</b>                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                   |                    |                                                                                                                                                              |     |      |      |             |
| Output Rise Time                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                    | $t_r$              | $C_L = 15 \text{ pF}$<br>See <a href="#">Figure 4.2 Propagation Delay Timing on page 15</a>                                                                  | —   | 2.5  | 4.0  | ns          |
| Output Fall Time                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                    | $t_f$              | $C_L = 15 \text{ pF}$<br>See <a href="#">Figure 4.2 Propagation Delay Timing on page 15</a>                                                                  | —   | 2.5  | 4.0  | ns          |
| Peak eye diagram jitter                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                             | $t_{JIT(PK)}$      | See <a href="#">Figure 2.3 Eye Diagram on page 6</a>                                                                                                         | —   | 350  | —    | ps          |
| Common Mode Transient Immunity                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                      | CMTI               | $V_I = V_{DD} \text{ or } 0 \text{ V}$<br>$V_{CM} = 1500 \text{ V}$ (see <a href="#">Figure 4.3 Common Mode Transient Immunity Test Circuit on page 15</a> ) | 35  | 50   | —    | kV/ $\mu$ s |
| Enable to Data Valid                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                | $t_{en1}$          | See <a href="#">Figure 4.1 ENABLE Timing Diagram on page 15</a>                                                                                              | —   | 6.0  | 11   | ns          |
| Enable to Data Tri-State                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                            | $t_{en2}$          | See <a href="#">Figure 4.1 ENABLE Timing Diagram on page 15</a>                                                                                              | —   | 8.0  | 12   | ns          |
| Start-up Time <sup>3</sup>                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                          | $t_{SU}$           |                                                                                                                                                              | —   | 15   | 40   | $\mu$ s     |
| <b>Notes:</b>                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                       |                    |                                                                                                                                                              |     |      |      |             |
| <ol style="list-style-type: none"> <li>The nominal output impedance of an isolator driver channel is approximately 50 <math>\Omega</math>, <math>\pm 40\%</math>, which is a combination of the value of the on-chip series termination resistor and channel resistance of the output driver FET. When driving loads where transmission line effects will be a factor, output pins should be appropriately terminated with controlled impedance PCB traces.</li> <li><math>t_{PSK(P-P)}</math> is the magnitude of the difference in propagation delay times measured between different units operating at the same supply voltages, load, and ambient temperature.</li> <li>Start-up time is the time period from the application of power to valid data at the output.</li> </ol> |                    |                                                                                                                                                              |     |      |      |             |

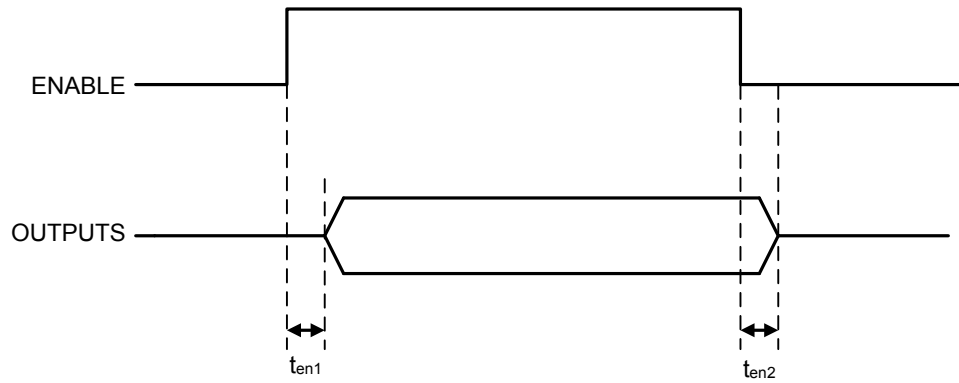


Figure 4.1. ENABLE Timing Diagram

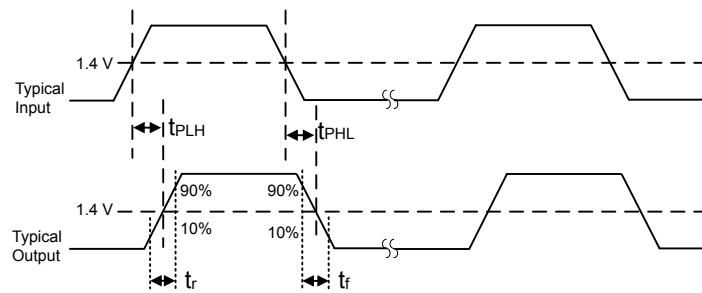


Figure 4.2. Propagation Delay Timing

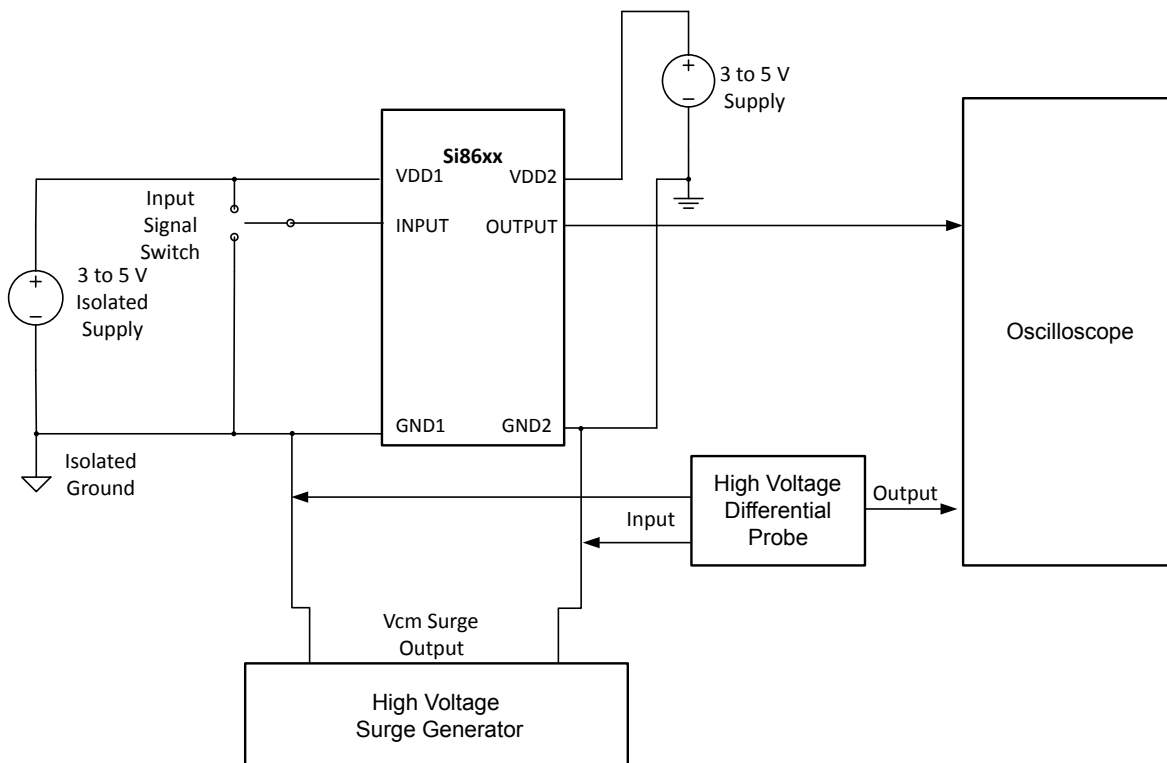


Figure 4.3. Common Mode Transient Immunity Test Circuit

**Table 4.3. Electrical Characteristics**(V<sub>DD1</sub> = 3.3 V±10%, V<sub>DD2</sub> = 3.3 V±10%, T<sub>A</sub> = –40 to 125 °C)

| Parameter                                                                           | Symbol             | Test Condition                              | Min                                       | Typ  | Max   | Unit |
|-------------------------------------------------------------------------------------|--------------------|---------------------------------------------|-------------------------------------------|------|-------|------|
| VDD Undervoltage Threshold                                                          | VDDUV+             | V <sub>DD1</sub> , V <sub>DD2</sub> rising  | 1.95                                      | 2.24 | 2.375 | V    |
| VDD Undervoltage Threshold                                                          | VDDUV–             | V <sub>DD1</sub> , V <sub>DD2</sub> falling | 1.88                                      | 2.16 | 2.325 | V    |
| VDD Undervoltage Hysteresis                                                         | VDD <sub>HYS</sub> |                                             | 50                                        | 70   | 95    | mV   |
| Positive-Going Input Threshold                                                      | VT+                | All inputs rising                           | 1.4                                       | 1.67 | 1.9   | V    |
| Negative-Going Input Threshold                                                      | VT–                | All inputs falling                          | 1.0                                       | 1.23 | 1.4   | V    |
| Input Hysteresis                                                                    | V <sub>HYS</sub>   |                                             | 0.38                                      | 0.44 | 0.50  | V    |
| High Level Input Voltage                                                            | V <sub>IH</sub>    |                                             | 2.0                                       | —    | —     | V    |
| Low Level Input Voltage                                                             | V <sub>IL</sub>    |                                             | —                                         | —    | 0.8   | V    |
| High Level Output Voltage                                                           | V <sub>OH</sub>    | I <sub>oh</sub> = –4 mA                     | V <sub>DD1</sub> , V <sub>DD2</sub> – 0.4 | 3.1  | —     | V    |
| Low Level Output Voltage                                                            | V <sub>OL</sub>    | I <sub>ol</sub> = 4 mA                      | —                                         | 0.2  | 0.4   | V    |
| Input Leakage Current                                                               | I <sub>L</sub>     |                                             | —                                         | —    | ±10   | μA   |
| Output Impedance <sup>1</sup>                                                       | Z <sub>O</sub>     |                                             | —                                         | 50   | —     | Ω    |
| Enable Input High Current                                                           | I <sub>ENH</sub>   | V <sub>ENx</sub> = V <sub>IH</sub>          | —                                         | 2.0  | —     | μA   |
| Enable Input Low Current                                                            | I <sub>ENL</sub>   | V <sub>ENx</sub> = V <sub>IL</sub>          | —                                         | 2.0  | —     | μA   |
| DC Supply Current (all Inputs 0 V or at Supply)                                     |                    |                                             |                                           |      |       |      |
| Si8650Bx, Ex, Si8655Bx                                                              |                    |                                             |                                           |      |       |      |
| V <sub>DD1</sub>                                                                    |                    | V <sub>I</sub> = 0(Bx), 1(Ex)               | —                                         | 1.1  | 1.8   | mA   |
| V <sub>DD2</sub>                                                                    |                    | V <sub>I</sub> = 0(Bx), 1(Ex)               | —                                         | 3.1  | 4.7   |      |
| V <sub>DD1</sub>                                                                    |                    | V <sub>I</sub> = 1(Bx), 0(Ex)               | —                                         | 7.0  | 9.8   |      |
| V <sub>DD2</sub>                                                                    |                    | V <sub>I</sub> = 1(Bx), 0(Ex)               | —                                         | 3.3  | 5.0   |      |
| Si8651Bx, Ex                                                                        |                    |                                             |                                           |      |       |      |
| V <sub>DD1</sub>                                                                    |                    | V <sub>I</sub> = 0(Bx), 1(Ex)               | —                                         | 1.5  | 2.4   | mA   |
| V <sub>DD2</sub>                                                                    |                    | V <sub>I</sub> = 0(Bx), 1(Ex)               | —                                         | 2.7  | 4.1   |      |
| V <sub>DD1</sub>                                                                    |                    | V <sub>I</sub> = 1(Bx), 0(Ex)               | —                                         | 6.6  | 9.2   |      |
| V <sub>DD2</sub>                                                                    |                    | V <sub>I</sub> = 1(Bx), 0(Ex)               | —                                         | 4.0  | 6.0   |      |
| Si8652Bx, Ex                                                                        |                    |                                             |                                           |      |       |      |
| V <sub>DD1</sub>                                                                    |                    | V <sub>I</sub> = 0(Bx), 1(Ex)               | —                                         | 2.0  | 3.0   | mA   |
| V <sub>DD2</sub>                                                                    |                    | V <sub>I</sub> = 0(Bx), 1(Ex)               | —                                         | 2.4  | 3.6   |      |
| V <sub>DD1</sub>                                                                    |                    | V <sub>I</sub> = 1(Bx), 0(Ex)               | —                                         | 5.6  | 7.8   |      |
| V <sub>DD2</sub>                                                                    |                    | V <sub>I</sub> = 1(Bx), 0(Ex)               | —                                         | 5.0  | 7.5   |      |
| 1 Mbps Supply Current (All Inputs = 500 kHz Square Wave, CI = 15 pF on All Outputs) |                    |                                             |                                           |      |       |      |
| Si8650Bx, Ex, Si8655Bx                                                              |                    |                                             |                                           |      |       |      |



| Parameter                                                                                   | Symbol             | Test Condition                                                     | Min | Typ  | Max  | Unit |
|---------------------------------------------------------------------------------------------|--------------------|--------------------------------------------------------------------|-----|------|------|------|
| $V_{DD1}$                                                                                   |                    |                                                                    | —   | 4.1  | 5.7  | mA   |
| $V_{DD2}$                                                                                   |                    |                                                                    | —   | 3.7  | 5.2  |      |
| <b>Si8651Bx, Ex</b>                                                                         |                    |                                                                    |     |      |      |      |
| $V_{DD1}$                                                                                   |                    |                                                                    | —   | 4.2  | 5.8  | mA   |
| $V_{DD2}$                                                                                   |                    |                                                                    | —   | 3.8  | 5.3  |      |
| <b>Si8652Bx, Ex</b>                                                                         |                    |                                                                    |     |      |      |      |
| $V_{DD1}$                                                                                   |                    |                                                                    | —   | 4.0  | 5.6  | mA   |
| $V_{DD2}$                                                                                   |                    |                                                                    | —   | 4.0  | 5.6  |      |
| <b>10 Mbps Supply Current (All Inputs = 5 MHz Square Wave, CI = 15 pF on All Outputs)</b>   |                    |                                                                    |     |      |      |      |
| <b>Si8650Bx, Ex, Si8655Bx</b>                                                               |                    |                                                                    |     |      |      |      |
| $V_{DD1}$                                                                                   |                    |                                                                    | —   | 4.1  | 5.7  | mA   |
| $V_{DD2}$                                                                                   |                    |                                                                    | —   | 4.4  | 6.1  |      |
| <b>Si8651Bx, Ex</b>                                                                         |                    |                                                                    |     |      |      |      |
| $V_{DD1}$                                                                                   |                    |                                                                    | —   | 4.3  | 6.0  | mA   |
| $V_{DD2}$                                                                                   |                    |                                                                    | —   | 4.3  | 6.0  |      |
| <b>Si8652Bx, Ex</b>                                                                         |                    |                                                                    |     |      |      |      |
| $V_{DD1}$                                                                                   |                    |                                                                    | —   | 4.3  | 6.0  | mA   |
| $V_{DD2}$                                                                                   |                    |                                                                    | —   | 4.4  | 6.1  |      |
| <b>100 Mbps Supply Current (All Inputs = 50 MHz Square Wave, CI = 15 pF on All Outputs)</b> |                    |                                                                    |     |      |      |      |
| <b>Si8650Bx, Ex, Si8655Bx</b>                                                               |                    |                                                                    |     |      |      |      |
| $V_{DD1}$                                                                                   |                    |                                                                    | —   | 4.1  | 5.7  | mA   |
| $V_{DD2}$                                                                                   |                    |                                                                    | —   | 15.5 | 20.1 |      |
| <b>Si8651Bx, Ex</b>                                                                         |                    |                                                                    |     |      |      |      |
| $V_{DD1}$                                                                                   |                    |                                                                    | —   | 6.6  | 8.9  | mA   |
| $V_{DD2}$                                                                                   |                    |                                                                    | —   | 13.2 | 17.1 |      |
| <b>Si8652Bx, Ex</b>                                                                         |                    |                                                                    |     |      |      |      |
| $V_{DD1}$                                                                                   |                    |                                                                    | —   | 8.9  | 11.6 | mA   |
| $V_{DD2}$                                                                                   |                    |                                                                    | —   | 11.1 | 14.4 |      |
| <b>Timing Characteristics</b>                                                               |                    |                                                                    |     |      |      |      |
| <b>Si865xBx, Ex</b>                                                                         |                    |                                                                    |     |      |      |      |
| Maximum Data Rate                                                                           |                    |                                                                    | 0   | —    | 150  | Mbps |
| Minimum Pulse Width                                                                         |                    |                                                                    | —   | —    | 5.0  | ns   |
| Propagation Delay                                                                           | $t_{PHL}, t_{PLH}$ | See <a href="#">Figure 4.2 Propagation Delay Timing on page 15</a> | 5.0 | 8.0  | 13   | ns   |
| Pulse Width Distortion<br>$ t_{PLH} - t_{PHL} $                                             | PWD                | See <a href="#">Figure 4.2 Propagation Delay Timing on page 15</a> | —   | 0.2  | 4.5  | ns   |

| Parameter                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                  | Symbol         | Test Condition                                                                                                               | Min | Typ | Max | Unit        |
|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|----------------|------------------------------------------------------------------------------------------------------------------------------|-----|-----|-----|-------------|
| Propagation Delay Skew <sup>2</sup>                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                        | $t_{PSK(P-P)}$ |                                                                                                                              | —   | 2.0 | 4.5 | ns          |
| Channel-Channel Skew                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                       | $t_{PSK}$      |                                                                                                                              | —   | 0.4 | 2.5 | ns          |
| <b>All Models</b>                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                          |                |                                                                                                                              |     |     |     |             |
| Output Rise Time                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                           | $t_r$          | $C_L = 15\text{ pF}$<br>See Figure 4.2 Propagation Delay Timing on page 15                                                   | —   | 2.5 | 4.0 | ns          |
| Output Fall Time                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                           | $t_f$          | $C_L = 15\text{ pF}$<br>(See Figure 4.2 Propagation Delay Timing on page 15)                                                 | —   | 2.5 | 4.0 | ns          |
| Peak eye diagram jitter                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                    | $t_{JIT(PK)}$  | See Figure 2.3 Eye Diagram on page 6                                                                                         | —   | 350 | —   | ps          |
| Common Mode Transient Immunity                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                             | CMTI           | $V_I = V_{DD}$ or 0 V<br>$V_{CM} = 1500\text{ V}$<br>(See Figure 4.3 Common Mode Transient Immunity Test Circuit on page 15) | 35  | 50  | —   | kV/ $\mu$ s |
| Enable to Data Valid                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                       | $t_{en1}$      | See Figure 4.1 ENABLE Timing Diagram on page 15                                                                              | —   | 6.0 | 11  | ns          |
| Enable to Data Tri-State                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                   | $t_{en2}$      | See Figure 4.1 ENABLE Timing Diagram on page 15                                                                              | —   | 8.0 | 12  | ns          |
| Start-Up Time <sup>3</sup>                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                 | $t_{SU}$       |                                                                                                                              | —   | 15  | 40  | $\mu$ s     |
| <b>Notes:</b> <ol style="list-style-type: none"> <li>1. The nominal output impedance of an isolator driver channel is approximately 50 <math>\Omega</math>, <math>\pm 40\%</math>, which is a combination of the value of the on-chip series termination resistor and channel resistance of the output driver FET. When driving loads where transmission line effects will be a factor, output pins should be appropriately terminated with controlled impedance PCB traces.</li> <li>2. <math>t_{PSK(P-P)}</math> is the magnitude of the difference in propagation delay times measured between different units operating at the same supply voltages, load, and ambient temperature.</li> <li>3. Start-up time is the time period from the application of power to valid data at the output.</li> </ol> |                |                                                                                                                              |     |     |     |             |

**Table 4.4. Electrical Characteristics**(V<sub>DD1</sub> = 2.5 V  $\pm 5\%$ , V<sub>DD2</sub> = 2.5 V  $\pm 5\%$ , T<sub>A</sub> = –40 to 125 °C)

| Parameter                      | Symbol           | Test Condition                              | Min                                       | Typ  | Max   | Unit |
|--------------------------------|------------------|---------------------------------------------|-------------------------------------------|------|-------|------|
| VDD Undervoltage Threshold     | VDDUV+           | V <sub>DD1</sub> , V <sub>DD2</sub> rising  | 1.95                                      | 2.24 | 2.375 | V    |
| VDD Undervoltage Threshold     | VDDUV–           | V <sub>DD1</sub> , V <sub>DD2</sub> falling | 1.88                                      | 2.16 | 2.325 | V    |
| VDD Undervoltage Hysteresis    | VDDHYS           |                                             | 50                                        | 70   | 95    | mV   |
| Positive-Going Input Threshold | VT+              | All inputs rising                           | 1.4                                       | 1.67 | 1.9   | V    |
| Negative-Going Input Threshold | VT–              | All inputs falling                          | 1.0                                       | 1.23 | 1.4   | V    |
| Input Hysteresis               | V <sub>HYS</sub> |                                             | 0.38                                      | 0.44 | 0.50  | V    |
| High Level Input Voltage       | V <sub>IH</sub>  |                                             | 2.0                                       | —    | —     | V    |
| Low Level Input Voltage        | V <sub>IL</sub>  |                                             | —                                         | —    | 0.8   | V    |
| High Level Output Voltage      | V <sub>OH</sub>  | I <sub>oh</sub> = –4 mA                     | V <sub>DD1</sub> , V <sub>DD2</sub> – 0.4 | 2.3  | —     | V    |

| Parameter                                                                           | Symbol           | Test Condition                     | Min | Typ | Max | Unit |
|-------------------------------------------------------------------------------------|------------------|------------------------------------|-----|-----|-----|------|
| Low Level Output Voltage                                                            | V <sub>OL</sub>  | I <sub>ol</sub> = 4 mA             | —   | 0.2 | 0.4 | V    |
| Input Leakage Current                                                               | I <sub>L</sub>   |                                    | —   | —   | ±10 | μA   |
| Output Impedance <sup>1</sup>                                                       | Z <sub>O</sub>   |                                    | —   | 50  | —   | Ω    |
| Enable Input High Current                                                           | I <sub>ENH</sub> | V <sub>ENx</sub> = V <sub>IH</sub> | —   | 2.0 | —   | μA   |
| Enable Input Low Current                                                            | I <sub>ENL</sub> | V <sub>ENx</sub> = V <sub>IL</sub> | —   | 2.0 | —   | μA   |
| DC Supply Current (All Inputs 0 V or at Supply)                                     |                  |                                    |     |     |     |      |
| Si8650Bx, Ex, Si8655Bx                                                              |                  |                                    |     |     |     |      |
| V <sub>DD1</sub>                                                                    |                  | V <sub>I</sub> = 0(Bx), 1(Ex)      | —   | 1.1 | 1.8 | mA   |
| V <sub>DD2</sub>                                                                    |                  | V <sub>I</sub> = 0(Bx), 1(Ex)      | —   | 3.1 | 4.7 |      |
| V <sub>DD1</sub>                                                                    |                  | V <sub>I</sub> = 1(Bx), 0(Ex)      | —   | 7.0 | 9.8 |      |
| V <sub>DD2</sub>                                                                    |                  | V <sub>I</sub> = 1(Bx), 0(Ex)      | —   | 3.3 | 5.0 |      |
| Si8651Bx, Ex                                                                        |                  |                                    |     |     |     |      |
| V <sub>DD1</sub>                                                                    |                  | V <sub>I</sub> = 0(Bx), 1(Ex)      | —   | 1.5 | 2.4 | mA   |
| V <sub>DD2</sub>                                                                    |                  | V <sub>I</sub> = 0(Bx), 1(Ex)      | —   | 2.7 | 4.1 |      |
| V <sub>DD1</sub>                                                                    |                  | V <sub>I</sub> = 1(Bx), 0(Ex)      | —   | 6.6 | 9.2 |      |
| V <sub>DD2</sub>                                                                    |                  | V <sub>I</sub> = 1(Bx), 0(Ex)      | —   | 4.0 | 6.0 |      |
| Si8652Bx, Ex                                                                        |                  |                                    |     |     |     |      |
| V <sub>DD1</sub>                                                                    |                  | V <sub>I</sub> = 0(Bx), 1(Ex)      | —   | 2.0 | 3.0 | mA   |
| V <sub>DD2</sub>                                                                    |                  | V <sub>I</sub> = 0(Bx), 1(Ex)      | —   | 2.4 | 3.6 |      |
| V <sub>DD1</sub>                                                                    |                  | V <sub>I</sub> = 1(Bx), 0(Ex)      | —   | 5.6 | 7.8 |      |
| V <sub>DD2</sub>                                                                    |                  | V <sub>I</sub> = 1(Bx), 0(Ex)      | —   | 5.0 | 7.5 |      |
| 1 Mbps Supply Current (All Inputs = 500 kHz Square Wave, CI = 15 pF on All Outputs) |                  |                                    |     |     |     |      |
| Si8650Bx, Ex, Si8655Bx                                                              |                  |                                    |     |     |     |      |
| V <sub>DD1</sub>                                                                    |                  |                                    | —   | 4.1 | 5.7 | mA   |
| V <sub>DD2</sub>                                                                    |                  |                                    | —   | 3.7 | 5.2 |      |
| Si8651Bx, Ex                                                                        |                  |                                    |     |     |     |      |
| V <sub>DD1</sub>                                                                    |                  |                                    | —   | 4.2 | 5.8 | mA   |
| V <sub>DD2</sub>                                                                    |                  |                                    | —   | 3.8 | 5.3 |      |
| Si8652Bx, Ex                                                                        |                  |                                    |     |     |     |      |
| V <sub>DD1</sub>                                                                    |                  |                                    | —   | 4.0 | 5.6 | mA   |
| V <sub>DD2</sub>                                                                    |                  |                                    | —   | 4.0 | 5.6 |      |
| 10 Mbps Supply Current (All Inputs = 5 MHz Square Wave, CI = 15 pF on All Outputs)  |                  |                                    |     |     |     |      |
| Si8650Bx, Ex, Si8655Bx                                                              |                  |                                    |     |     |     |      |
| V <sub>DD1</sub>                                                                    |                  |                                    | —   | 4.1 | 5.7 | mA   |
| V <sub>DD2</sub>                                                                    |                  |                                    | —   | 4.0 | 5.6 |      |

| Parameter                                                                                   | Symbol             | Test Condition                                                                      | Min | Typ  | Max  | Unit |
|---------------------------------------------------------------------------------------------|--------------------|-------------------------------------------------------------------------------------|-----|------|------|------|
| <b>Si8651Bx, Ex</b>                                                                         |                    |                                                                                     |     |      |      |      |
| $V_{DD1}$                                                                                   |                    |                                                                                     | —   | 4.2  | 5.9  | mA   |
| $V_{DD2}$                                                                                   |                    |                                                                                     | —   | 4.0  | 5.6  |      |
| <b>Si8652Bx, Ex</b>                                                                         |                    |                                                                                     |     |      |      |      |
| $V_{DD1}$                                                                                   |                    |                                                                                     | —   | 4.1  | 5.8  | mA   |
| $V_{DD2}$                                                                                   |                    |                                                                                     | —   | 4.2  | 5.9  |      |
| <b>100 Mbps Supply Current (All Inputs = 50 MHz Square Wave, CI = 15 pF on All Outputs)</b> |                    |                                                                                     |     |      |      |      |
| <b>Si8650Bx, Ex, Si8655Bx</b>                                                               |                    |                                                                                     |     |      |      |      |
| $V_{DD1}$                                                                                   |                    |                                                                                     | —   | 4.1  | 5.7  | mA   |
| $V_{DD2}$                                                                                   |                    |                                                                                     | —   | 12.5 | 16.2 |      |
| <b>Si8651Bx, Ex</b>                                                                         |                    |                                                                                     |     |      |      |      |
| $V_{DD1}$                                                                                   |                    |                                                                                     | —   | 6.0  | 8.1  | mA   |
| $V_{DD2}$                                                                                   |                    |                                                                                     | —   | 10.8 | 14   |      |
| <b>Si8652Bx, Ex</b>                                                                         |                    |                                                                                     |     |      |      |      |
| $V_{DD1}$                                                                                   |                    |                                                                                     | —   | 7.6  | 9.9  | mA   |
| $V_{DD2}$                                                                                   |                    |                                                                                     | —   | 9.3  | 12.0 |      |
| <b>Timing Characteristics</b>                                                               |                    |                                                                                     |     |      |      |      |
| <b>Si865xBx, Ex</b>                                                                         |                    |                                                                                     |     |      |      |      |
| Maximum Data Rate                                                                           |                    |                                                                                     | 0   | —    | 150  | Mbps |
| Minimum Pulse Width                                                                         |                    |                                                                                     | —   | —    | 5.0  | ns   |
| Propagation Delay                                                                           | $t_{PHL}, t_{PLH}$ | See <a href="#">Figure 4.2 Propagation Delay Timing on page 15</a>                  | 5.0 | 8.0  | 14   | ns   |
| Pulse Width Distortion<br>  $t_{PLH} - t_{PHL}$                                             | PWD                | See <a href="#">Figure 4.2 Propagation Delay Timing on page 15</a>                  | —   | 0.2  | 5.0  | ns   |
| Propagation Delay Skew <sup>2</sup>                                                         | $t_{PSK(P-P)}$     |                                                                                     | —   | 2.0  | 5.0  | ns   |
| Channel-Channel Skew                                                                        | $t_{PSK}$          |                                                                                     | —   | 0.4  | 2.5  | ns   |
| <b>All Models</b>                                                                           |                    |                                                                                     |     |      |      |      |
| Output Rise Time                                                                            | $t_r$              | $C_L = 15$ pF<br>See <a href="#">Figure 4.2 Propagation Delay Timing on page 15</a> | —   | 2.5  | 4.0  | ns   |
| Output Fall Time                                                                            | $t_f$              | $C_L = 15$ pF<br>See <a href="#">Figure 4.2 Propagation Delay Timing on page 15</a> | —   | 2.5  | 4.0  | ns   |
| Peak Eye Diagram Jitter                                                                     | $t_{JIT(PK)}$      | See <a href="#">Figure 2.3 Eye Diagram on page 6</a>                                | —   | 350  | —    | ps   |

| Parameter                      | Symbol    | Test Condition                                                                                                                          | Min | Typ | Max | Unit        |
|--------------------------------|-----------|-----------------------------------------------------------------------------------------------------------------------------------------|-----|-----|-----|-------------|
| Common Mode Transient Immunity | CMTI      | $V_I = V_{DD}$ or 0 V<br><br>$V_{CM} = 1500$ V (See <a href="#">Figure 4.3 Common Mode Transient Immunity Test Circuit on page 15</a> ) | 35  | 50  | —   | kV/ $\mu$ s |
| Enable to Data Valid           | $t_{en1}$ | See <a href="#">Figure 4.1 ENABLE Timing Diagram on page 15</a>                                                                         | —   | 6.0 | 11  | ns          |
| Enable to Data Tri-State       | $t_{en2}$ | See <a href="#">Figure 4.1 ENABLE Timing Diagram on page 15</a>                                                                         | —   | 8.0 | 12  | ns          |
| Startup Time <sup>3</sup>      | $t_{SU}$  |                                                                                                                                         | —   | 15  | 40  | $\mu$ s     |

**Notes:**

1. The nominal output impedance of an isolator driver channel is approximately 50  $\Omega$ ,  $\pm 40\%$ , which is a combination of the value of the on-chip series termination resistor and channel resistance of the output driver FET. When driving loads where transmission line effects will be a factor, output pins should be appropriately terminated with controlled impedance PCB traces.
2.  $t_{PSK(P-P)}$  is the magnitude of the difference in propagation delay times measured between different units operating at the same supply voltages, load, and ambient temperature.
3. Start-up time is the time period from the application of power to valid data at the output.

**Table 4.5. Regulatory Information <sup>1</sup>**

|                                                                                                                                                                                                                                                                                                                                                                                                                                                                                           |
|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| <b>CSA</b>                                                                                                                                                                                                                                                                                                                                                                                                                                                                                |
| The Si865x is certified under CSA Component Acceptance Notice 5A. For more details, see Master Contract Number 232873.                                                                                                                                                                                                                                                                                                                                                                    |
| 60950-1, 62368-1: Up to 600 V <sub>RMS</sub> reinforced insulation working voltage; up to 1000 V <sub>RMS</sub> basic insulation working voltage.                                                                                                                                                                                                                                                                                                                                         |
| 60601-1: Up to 250 V <sub>RMS</sub> working voltage and 2 MOPP (Means of Patient Protection).                                                                                                                                                                                                                                                                                                                                                                                             |
| <b>VDE</b>                                                                                                                                                                                                                                                                                                                                                                                                                                                                                |
| The Si865x is certified according to VDE 0884-10. For more details, see certificate 40018443.                                                                                                                                                                                                                                                                                                                                                                                             |
| 0884-10: Up to 1200 V <sub>peak</sub> for basic insulation working voltage.                                                                                                                                                                                                                                                                                                                                                                                                               |
| 60950-1: Up to 600 V <sub>RMS</sub> reinforced insulation working voltage; up to 1000 V <sub>RMS</sub> basic insulation working voltage.                                                                                                                                                                                                                                                                                                                                                  |
| <b>UL</b>                                                                                                                                                                                                                                                                                                                                                                                                                                                                                 |
| The Si865x is certified under UL1577 component recognition program. For more details, see File E257455.                                                                                                                                                                                                                                                                                                                                                                                   |
| Rated up to 5000 V <sub>RMS</sub> isolation voltage for basic protection.                                                                                                                                                                                                                                                                                                                                                                                                                 |
| <b>CQC</b>                                                                                                                                                                                                                                                                                                                                                                                                                                                                                |
| The Si865x is certified under GB4943.1-2011. For more details, see certificates CQC13001096110 and CQC13001096239.                                                                                                                                                                                                                                                                                                                                                                        |
| Rated up to 600 V <sub>RMS</sub> reinforced insulation working voltage; up to 1000 V <sub>RMS</sub> basic insulation working voltage.                                                                                                                                                                                                                                                                                                                                                     |
| <b>Note:</b>                                                                                                                                                                                                                                                                                                                                                                                                                                                                              |
| 1. Regulatory Certifications apply to 2.5 kV <sub>RMS</sub> rated devices which are production tested to 3.0 kV <sub>RMS</sub> for 1 sec. Regulatory Certifications apply to 3.75 kV <sub>RMS</sub> rated devices which are production tested to 4.5 kV <sub>RMS</sub> for 1 sec. Regulatory Certifications apply to 5.0 kV <sub>RMS</sub> rated devices which are production tested to 6.0 kV <sub>RMS</sub> for 1 sec.<br>For more information, see <a href="#">1. Ordering Guide</a> . |

**Table 4.6. Insulation and Safety-Related Specifications**

| Parameter                                         | Symbol          | Test Condition | Value            |                  |                  | Unit             |
|---------------------------------------------------|-----------------|----------------|------------------|------------------|------------------|------------------|
|                                                   |                 |                | WB SOIC-16       | NB SOIC-16       | QSOP-16          |                  |
| Nominal External Air Gap (Clearance) <sup>1</sup> | CLR             |                | 8.0              | 4.9              | 3.6              | mm               |
| Nominal External Tracking (Creepage) <sup>1</sup> | CPG             |                | 8.0              | 4.01             | 3.6              | mm               |
| Minimum Internal Gap<br>(Internal Clearance)      | DTI             |                | 0.014            | 0.014            | 0.014            | mm               |
| Tracking Resistance                               | CTI or PTI      | IEC60112       | 600              | 600              | 600              | V <sub>RMS</sub> |
| Erosion Depth                                     | ED              |                | 0.019            | 0.019            | 0.031            | mm               |
| Resistance (Input-Output) <sup>2</sup>            | R <sub>IO</sub> |                | 10 <sup>12</sup> | 10 <sup>12</sup> | 10 <sup>12</sup> | Ω                |
| Capacitance (Input-Output) <sup>2</sup>           | C <sub>IO</sub> | f = 1 MHz      | 2.0              | 2.0              | 2.0              | pF               |
| Input Capacitance <sup>3</sup>                    | C <sub>I</sub>  |                | 4.0              | 4.0              | 4.0              | pF               |

**Note:**

1. The values in this table correspond to the nominal creepage and clearance values. VDE certifies the clearance and creepage limits as 4.7 mm minimum for the NB SOIC-16 package and QSOP-16 packages and 8.5 mm minimum for the WB SOIC-16 package. UL does not impose a clearance and creepage minimum for component-level certifications. CSA certifies the clearance and creepage of the WB SOIC-16 package with designation "IS2" as 8 mm minimum. CSA certifies the clearance and creepage limits as 3.9 mm minimum for the NB SOIC 16, 3.6 mm minimum for the QSOP-16, and 7.6 mm minimum for the WB SOIC-16 package with package designation "IS" as listed in the data sheet.
2. To determine resistance and capacitance, the Si86xx is converted into a 2-terminal device. Pins 1–8 are shorted together to form the first terminal and pins 9–16 are shorted together to form the second terminal. The parameters are then measured between these two terminals.
3. Measured from input pin to ground.

**Table 4.7. IEC 60664-1 Ratings**

| Parameter                   | Test Conditions                             | Specification |            |         |
|-----------------------------|---------------------------------------------|---------------|------------|---------|
|                             |                                             | WB SOIC-16    | NB SOIC-16 | QSOP-16 |
| Basic Isolation Group       | Material Group                              | I             | I          | I       |
| Installation Classification | Rated Mains Voltages ≤ 150 V <sub>RMS</sub> | I-IV          | I-IV       | I-IV    |
|                             | Rated Mains Voltages ≤ 300 V <sub>RMS</sub> | I-IV          | I-III      | I-III   |
|                             | Rated Mains Voltages ≤ 400 V <sub>RMS</sub> | I-III         | I-II       | I-II    |
|                             | Rated Mains Voltages ≤ 600 V <sub>RMS</sub> | I-III         | I-II       | I-II    |

Table 4.8. VDE 0884-10 Insulation Characteristics for Si86xxxx<sup>1</sup>

| Parameter                                                            | Symbol            | Test Condition                                                                                                                            | Characteristic   |                  |                  | Unit              |
|----------------------------------------------------------------------|-------------------|-------------------------------------------------------------------------------------------------------------------------------------------|------------------|------------------|------------------|-------------------|
|                                                                      |                   |                                                                                                                                           | WB SOIC-16       | NB SOIC-16       | QSOP-16          |                   |
| Maximum Working Insulation Voltage                                   | V <sub>IORM</sub> |                                                                                                                                           | 1200             | 630              | 630              | V <sub>peak</sub> |
| Input to Output Test Voltage                                         | V <sub>PR</sub>   | Method b1<br>(V <sub>IORM</sub> × 1.875 = V <sub>PR</sub> , 100%<br>Production Test, t <sub>m</sub> = 1 sec,<br>Partial Discharge < 5 pC) | 2250             | 1182             | 1182             | V <sub>peak</sub> |
| Transient Overvoltage                                                | V <sub>IOTM</sub> | t = 60 sec                                                                                                                                | 6000             | 6000             | 6000             | V <sub>peak</sub> |
| Surge Voltage                                                        | V <sub>IOSM</sub> | Tested per IEC 60065 with surge<br>voltage of 1.2 μs/50 μs<br>Si865xxB/C/D tested with 4000 V                                             | 3077             | 3077             | 3077             | V <sub>peak</sub> |
| Pollution Degree<br>(DIN VDE 0110, Table 1)                          |                   |                                                                                                                                           | 2                | 2                | 2                |                   |
| Insulation Resistance at T <sub>S</sub> , V <sub>IO</sub><br>= 500 V | R <sub>S</sub>    |                                                                                                                                           | >10 <sup>9</sup> | >10 <sup>9</sup> | >10 <sup>9</sup> | Ω                 |

**Note:**

1. Maintenance of the safety data is ensured by protective circuits. The Si86xxxx provides a climate classification of 40/125/21.

Table 4.9. VDE 0884-10 Safety Limiting Values<sup>1</sup>

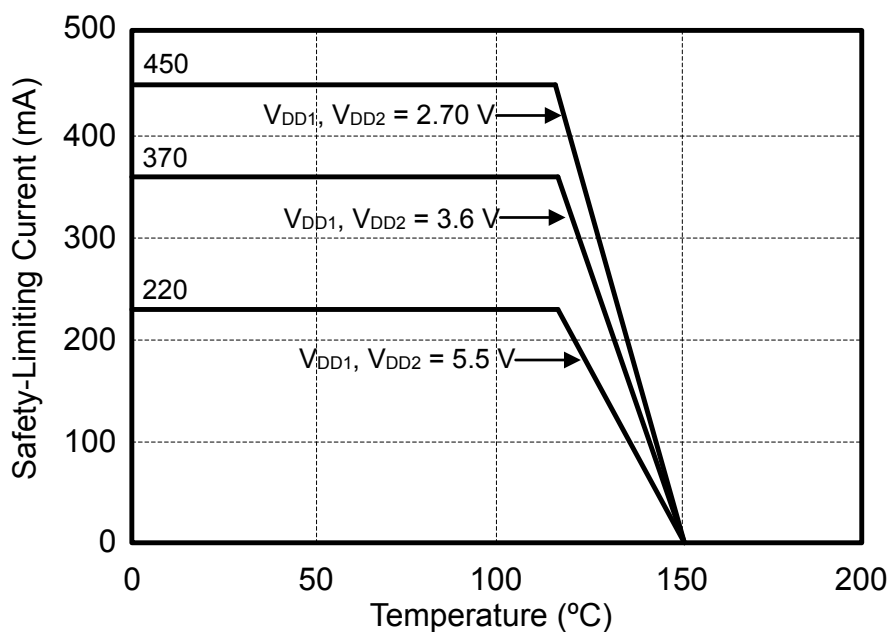
| Parameter                               | Symbol         | Test Condition                                                                                                                                       | Max        |            |         | Unit |
|-----------------------------------------|----------------|------------------------------------------------------------------------------------------------------------------------------------------------------|------------|------------|---------|------|
|                                         |                |                                                                                                                                                      | WB SOIC-16 | NB SOIC-16 | QSOP-16 |      |
| Case Temperature                        | T <sub>S</sub> |                                                                                                                                                      | 150        | 150        | 150     | °C   |
| Safety Input, Output, or Supply Current | I <sub>S</sub> | θ <sub>JA</sub> = 100 °C/W (WB SOIC-16)<br>105 °C/W (NB SOIC-16, QSOP-16)<br>V <sub>I</sub> = 5.5 V, T <sub>J</sub> = 150 °C, T <sub>A</sub> = 25 °C | 220        | 215        | 215     | mA   |
| Device Power Dissipation <sup>2</sup>   | P <sub>D</sub> |                                                                                                                                                      | 415        | 415        | 415     | mW   |

**Note:**

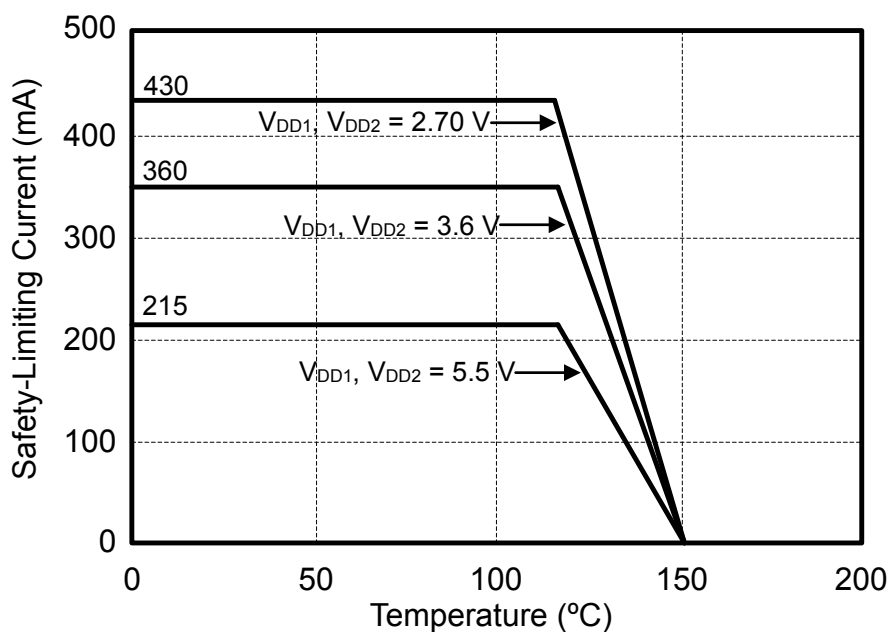
- Maximum value allowed in the event of a failure; also see the thermal derating curve in [Figure 4.4 \(WB SOIC-16\) Thermal Derating Curve, Dependence of Safety Limiting Values with Case Temperature per VDE 0884-10 on page 24](#) and [Figure 4.5 \(NB SOIC-16, QSOP-16\) Thermal Derating Curve, Dependence of Safety Limiting Values with Case Temperature per VDE 0884-10 on page 24](#).
- The Si86xx is tested with VDD1 = VDD2 = 5.5 V; T<sub>J</sub> = 150 °C; C<sub>L</sub> = 15 pF, input a 150 Mbps 50% duty cycle square wave.

**Table 4.10. Thermal Characteristics**

| Parameter                             | Symbol        | WB SOIC-16 | NB SOIC-16/QSOP-16 | Unit                        |
|---------------------------------------|---------------|------------|--------------------|-----------------------------|
| IC Junction-to-Air Thermal Resistance | $\theta_{JA}$ | 100        | 105                | $^{\circ}\text{C}/\text{W}$ |



**Figure 4.4. (WB SOIC-16) Thermal Derating Curve, Dependence of Safety Limiting Values with Case Temperature per VDE 0884-10**



**Figure 4.5. (NB SOIC-16, QSOP-16) Thermal Derating Curve, Dependence of Safety Limiting Values with Case Temperature per VDE 0884-10**



**Table 4.11. Absolute Maximum Ratings <sup>1</sup>**

| Parameter                                                             | Symbol             | Min  | Max            | Unit      |
|-----------------------------------------------------------------------|--------------------|------|----------------|-----------|
| Storage Temperature <sup>2</sup>                                      | $T_{STG}$          | –65  | 150            | °C        |
| Ambient Temperature Under Bias                                        | $T_A$              | –40  | 125            | °C        |
| Junction Temperature                                                  | $T_J$              | —    | 150            | °C        |
| Supply Voltage                                                        | $V_{DD1}, V_{DD2}$ | –0.5 | 7.0            | V         |
| Input Voltage                                                         | $V_I$              | –0.5 | $V_{DD} + 0.5$ | V         |
| Output Voltage                                                        | $V_O$              | –0.5 | $V_{DD} + 0.5$ | V         |
| Output Current Drive Channel<br>(All devices unless otherwise stated) | $I_O$              | —    | 10             | mA        |
| Output Current Drive Channel<br>(All Si865xxA-x-xx devices)           | $I_O$              | —    | 22             | mA        |
| Latchup Immunity <sup>3</sup>                                         |                    | —    | 100            | V/ns      |
| Lead Solder Temperature (10 s)                                        |                    | —    | 260            | °C        |
| Maximum Isolation (Input to Output) (1 sec)<br>NB SOIC-16, QSOP-16    |                    | —    | 4500           | $V_{RMS}$ |
| Maximum Isolation (Input to Output) (1 sec)<br>WB SOIC-16             |                    | —    | 6500           | $V_{RMS}$ |

**Notes:**

1. Permanent device damage may occur if the absolute maximum ratings are exceeded. Functional operation should be restricted to conditions as specified in the operational sections of this data sheet.
2. VDE certifies storage temperature from –40 to 150 °C.
3. Latchup immunity specification is for slew rate applied across GND1 and GND2.

## 5. Pin Descriptions

### 5.1 Si8650/51/52 Pin Descriptions

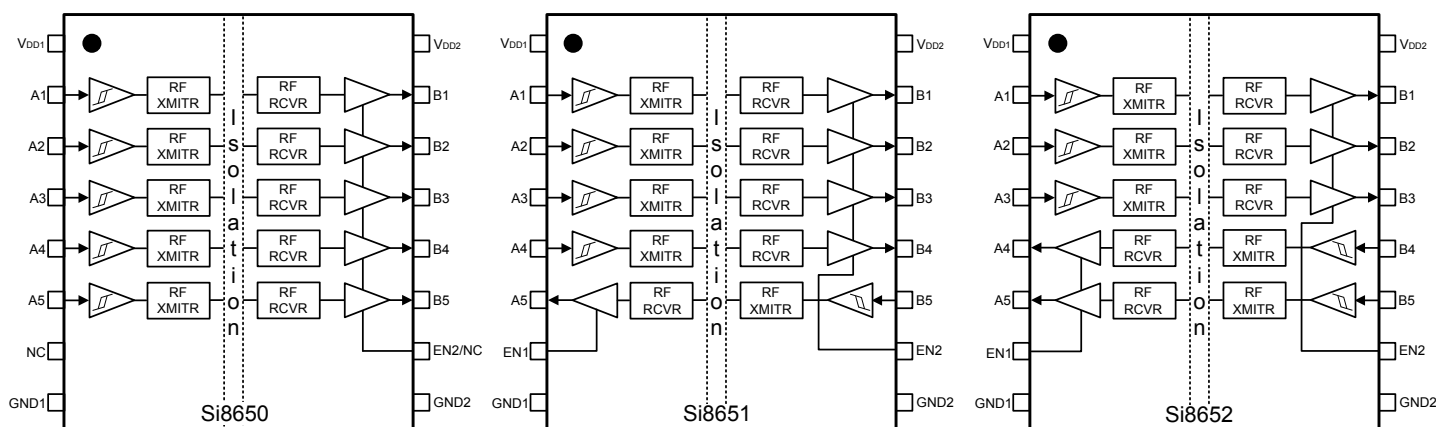


Figure 5.1. Si8650/51/52 Pinout

Table 5.1. Si8650/51/52 Pin Descriptions

| Name                | SOIC-16 Pin# | Type           | Description                              |
|---------------------|--------------|----------------|------------------------------------------|
| V <sub>DD1</sub>    | 1            | Supply         | Side 1 power supply.                     |
| A1                  | 2            | Digital Input  | Side 1 digital input.                    |
| A2                  | 3            | Digital Input  | Side 1 digital input.                    |
| A3                  | 4            | Digital Input  | Side 1 digital input.                    |
| A4                  | 5            | Digital I/O    | Side 1 digital input or output.          |
| A5                  | 6            | Digital I/O    | Side 1 digital input or output.          |
| EN1/NC <sup>1</sup> | 7            | Digital Input  | Side 1 active high enable. NC on Si8650. |
| GND1                | 8            | Ground         | Side 1 ground.                           |
| GND2                | 9            | Ground         | Side 2 ground.                           |
| EN2                 | 10           | Digital Input  | Side 2 active high enable.               |
| B5                  | 11           | Digital I/O    | Side 2 digital input or output.          |
| B4                  | 12           | Digital I/O    | Side 2 digital input or output.          |
| B3                  | 13           | Digital Output | Side 2 digital output.                   |
| B2                  | 14           | Digital Output | Side 2 digital output.                   |
| B1                  | 15           | Digital Output | Side 2 digital output.                   |
| V <sub>DD2</sub>    | 16           | Supply         | Side 2 power supply.                     |

**Note:**

1. No Connect. These pins are not internally connected. They can be left floating, tied to V<sub>DD</sub> or tied to GND.

## 5.2 Si8655 Pin Descriptions

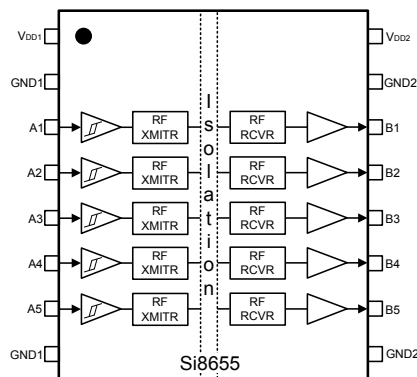


Figure 5.2. Si8655 Pinout

Table 5.2. Si8655 Pin Descriptions

| Name             | SOIC-16 Pin#    | Type           | Description            |
|------------------|-----------------|----------------|------------------------|
| V <sub>DD1</sub> | 1               | Supply         | Side 1 power supply.   |
| GND1             | 2 <sup>1</sup>  | Ground         | Side 1 ground.         |
| A1               | 3               | Digital Input  | Side 1 digital input.  |
| A2               | 4               | Digital Input  | Side 1 digital input.  |
| A3               | 5               | Digital Input  | Side 1 digital input.  |
| A4               | 6               | Digital Input  | Side 1 digital input.  |
| A5               | 7               | Digital Input  | Side 1 digital input.  |
| GND1             | 8 <sup>1</sup>  | Ground         | Side 1 ground.         |
| GND2             | 9 <sup>1</sup>  | Ground         | Side 2 ground.         |
| B5               | 10              | Digital Output | Side 2 digital output. |
| B4               | 11              | Digital Output | Side 2 digital output. |
| B3               | 12              | Digital Output | Side 2 digital output. |
| B2               | 13              | Digital Output | Side 2 digital output. |
| B1               | 14              | Digital Output | Side 2 digital output. |
| GND2             | 15 <sup>1</sup> | Ground         | Side 2 ground.         |
| V <sub>DD2</sub> | 16              | Supply         | Side 2 power supply.   |

**Note:**

1. For narrow-body devices, Pin 2 and Pin 8 GND must be externally connected to respective ground. Pin 9 and Pin 15 must also be connected to external ground.

6. Package Outline (16-Pin Wide Body SOIC)

The figure below illustrates the package details for the Si86xx digital isolator in a 16-pin wide-body SOIC package. The table below lists the values for the dimensions shown in the illustration.

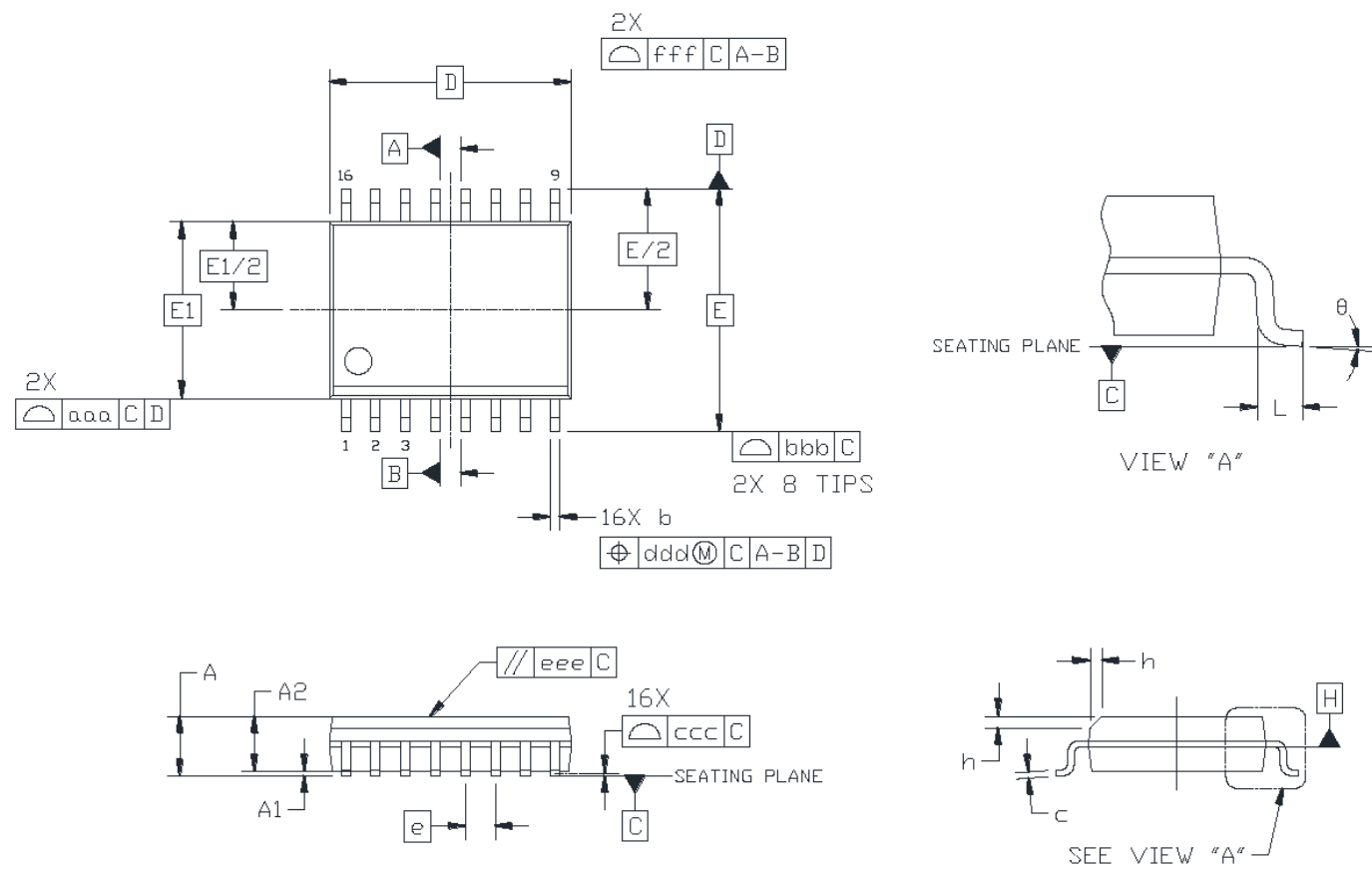


Figure 6.1. 16-Pin Wide Body SOIC

Table 6.1. 16-Pin Wide Body SOIC Package Diagram Dimensions

| Dimension | Min       | Max  |
|-----------|-----------|------|
| A         | —         | 2.65 |
| A1        | 0.10      | 0.30 |
| A2        | 2.05      | —    |
| b         | 0.31      | 0.51 |
| c         | 0.20      | 0.33 |
| D         | 10.30 BSC |      |
| E         | 10.30 BSC |      |
| E1        | 7.50 BSC  |      |
| e         | 1.27 BSC  |      |
| L         | 0.40      | 1.27 |
| h         | 0.25      | 0.75 |
| θ         | 0°        | 8°   |
| aaa       | —         | 0.10 |
| bbb       | —         | 0.33 |
| ccc       | —         | 0.10 |
| ddd       | —         | 0.25 |
| eee       | —         | 0.10 |
| fff       | —         | 0.20 |

**Notes:**

1. All dimensions shown are in millimeters (mm) unless otherwise noted.
2. Dimensioning and Tolerancing per ANSI Y14.5M-1994.
3. This drawing conforms to JEDEC Outline MS-013, Variation AA.
4. Recommended reflow profile per JEDEC J-STD-020 specification for small body, lead-free components.

7. Land Pattern (16-Pin Wide-Body SOIC)

The figure below illustrates the recommended land pattern details for the Si86xx in a 16-pin wide-body SOIC package. The table below lists the values for the dimensions shown in the illustration.

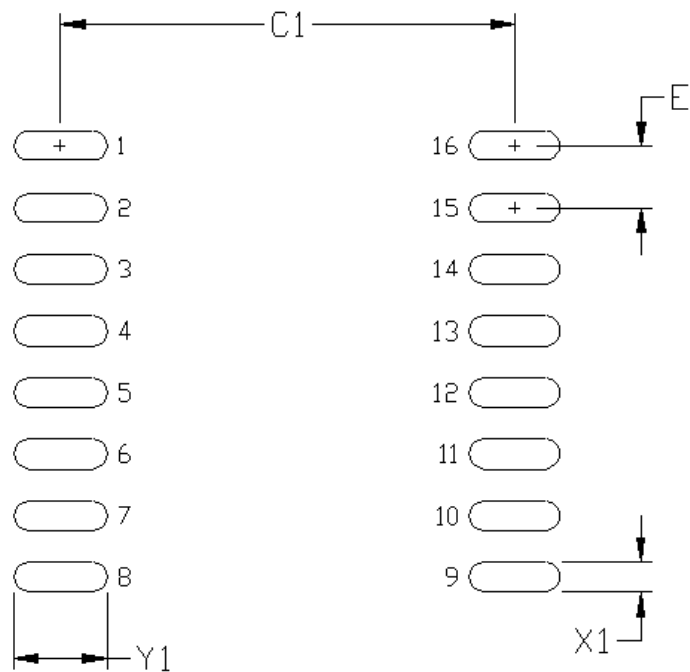


Figure 7.1. 16-Pin Wide Body SOIC PCB Land Pattern

Table 7.1. 16-Pin Wide Body SOIC Land Pattern Dimensions

| Dimension | Feature            | (mm) |
|-----------|--------------------|------|
| C1        | Pad Column Spacing | 9.40 |
| E         | Pad Row Pitch      | 1.27 |
| X1        | Pad Width          | 0.60 |
| Y1        | Pad Length         | 1.90 |

Notes:

- 1. This Land Pattern Design is based on IPC-7351 pattern SOIC127P1032X265-16AN for Density Level B (Median Land Protrusion).
- 2. All feature sizes shown are at Maximum Material Condition (MMC) and a card fabrication tolerance of 0.05 mm is assumed.

## 8. Package Outline (16-Pin Narrow Body SOIC)

The figure below illustrates the package details for the Si86xx in a 16-pin narrow-body SOIC package. The table below lists the values for the dimensions shown in the illustration.

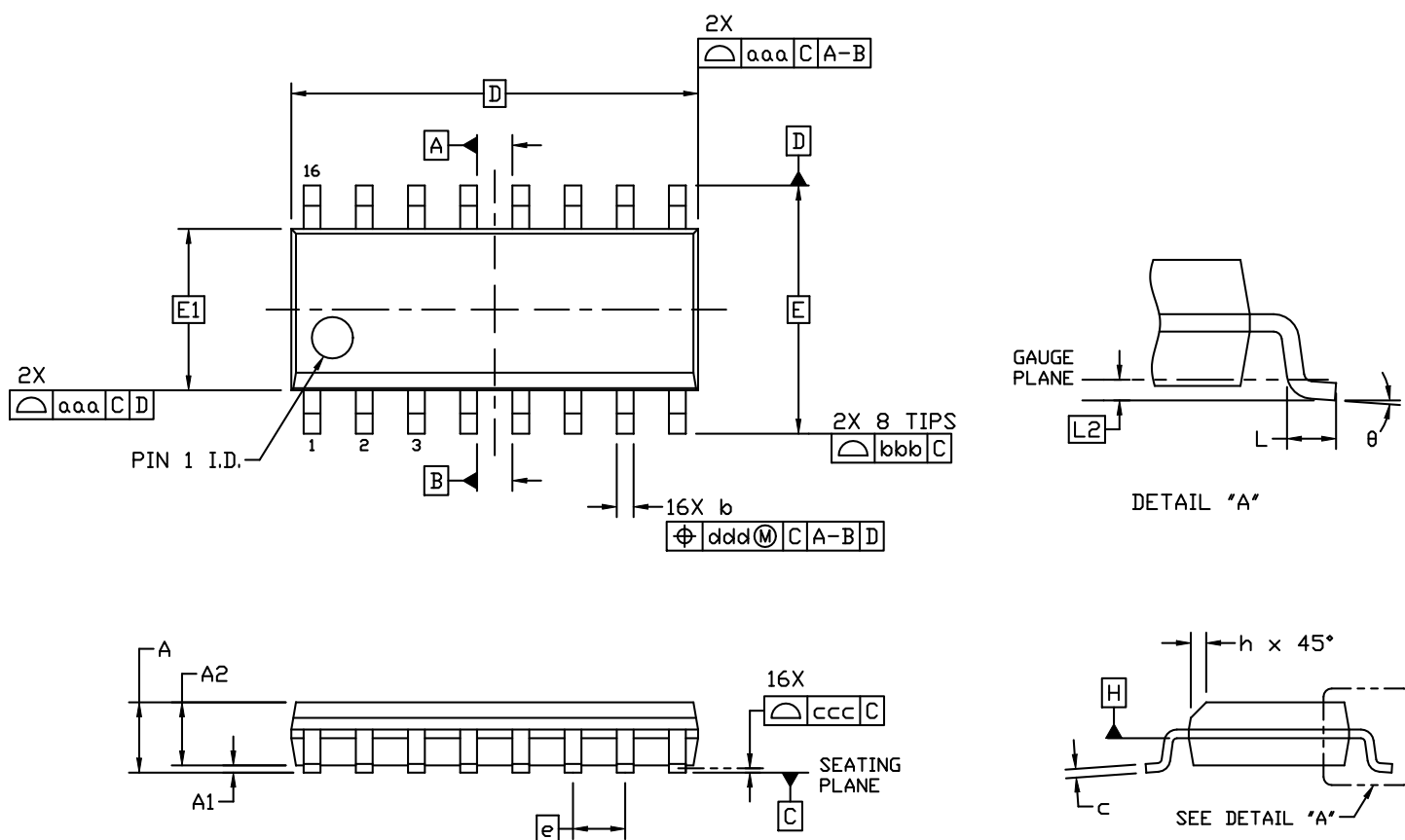


Figure 8.1. 16-Pin Narrow Body SOIC

Table 8.1. 16-Pin Narrow Body SOIC Package Diagram Dimensions

| Dimension | Min      | Max  |
|-----------|----------|------|
| A         | —        | 1.75 |
| A1        | 0.10     | 0.25 |
| A2        | 1.25     | —    |
| b         | 0.31     | 0.51 |
| c         | 0.17     | 0.25 |
| D         | 9.90 BSC |      |
| E         | 6.00 BSC |      |
| E1        | 3.90 BSC |      |
| e         | 1.27 BSC |      |
| L         | 0.40     | 1.27 |
| L2        | 0.25 BSC |      |
| h         | 0.25     | 0.50 |
| θ         | 0°       | 8°   |
| aaa       | 0.10     |      |
| bbb       | 0.20     |      |
| ccc       | 0.10     |      |
| ddd       | 0.25     |      |

**Notes:**

1. All dimensions shown are in millimeters (mm) unless otherwise noted.
2. Dimensioning and Tolerancing per ANSI Y14.5M-1994.
3. This drawing conforms to the JEDEC Solid State Outline MS-012, Variation AC.
4. Recommended card reflow profile is per the JEDEC/IPC J-STD-020 specification for Small Body Components.



## 9. Land Pattern (16-Pin Narrow Body SOIC)

The figure below illustrates the recommended land pattern details for the Si86xx in a 16-pin narrow-body SOIC package. The table below lists the values for the dimensions shown in the illustration.

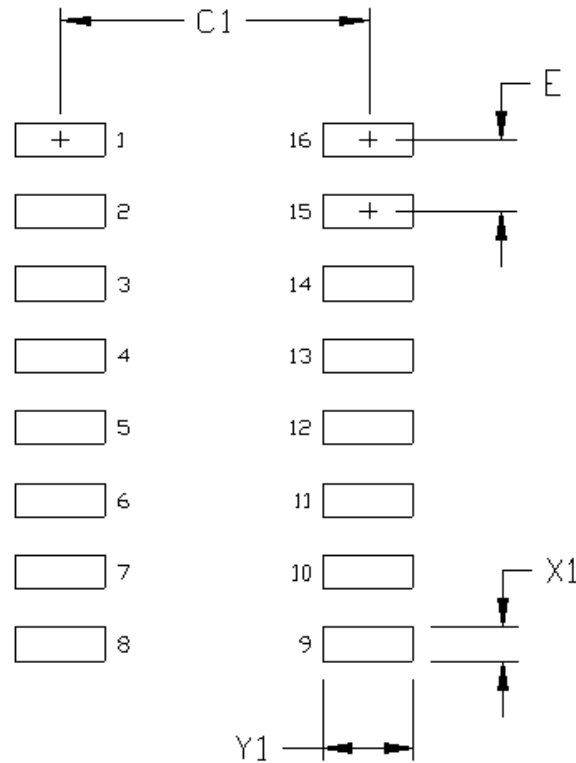


Figure 9.1. 16-Pin Narrow Body SOIC PCB Land Pattern

Table 9.1. 16-Pin Narrow Body SOIC Land Pattern Dimensions

| Dimension | Feature            | (mm) |
|-----------|--------------------|------|
| C1        | Pad Column Spacing | 5.40 |
| E         | Pad Row Pitch      | 1.27 |
| X1        | Pad Width          | 0.60 |
| Y1        | Pad Length         | 1.55 |

**Notes:**

1. This Land Pattern Design is based on IPC-7351 pattern SOIC127P600X165-16N for Density Level B (Median Land Protrusion).
2. All feature sizes shown are at Maximum Material Condition (MMC) and a card fabrication tolerance of 0.05 mm is assumed.

10. Package Outline (16-Pin QSOP)

The figure below illustrates the package details for the Si86xx in a 16-pin QSOP package. The table below lists the values for the dimensions shown in the illustration.

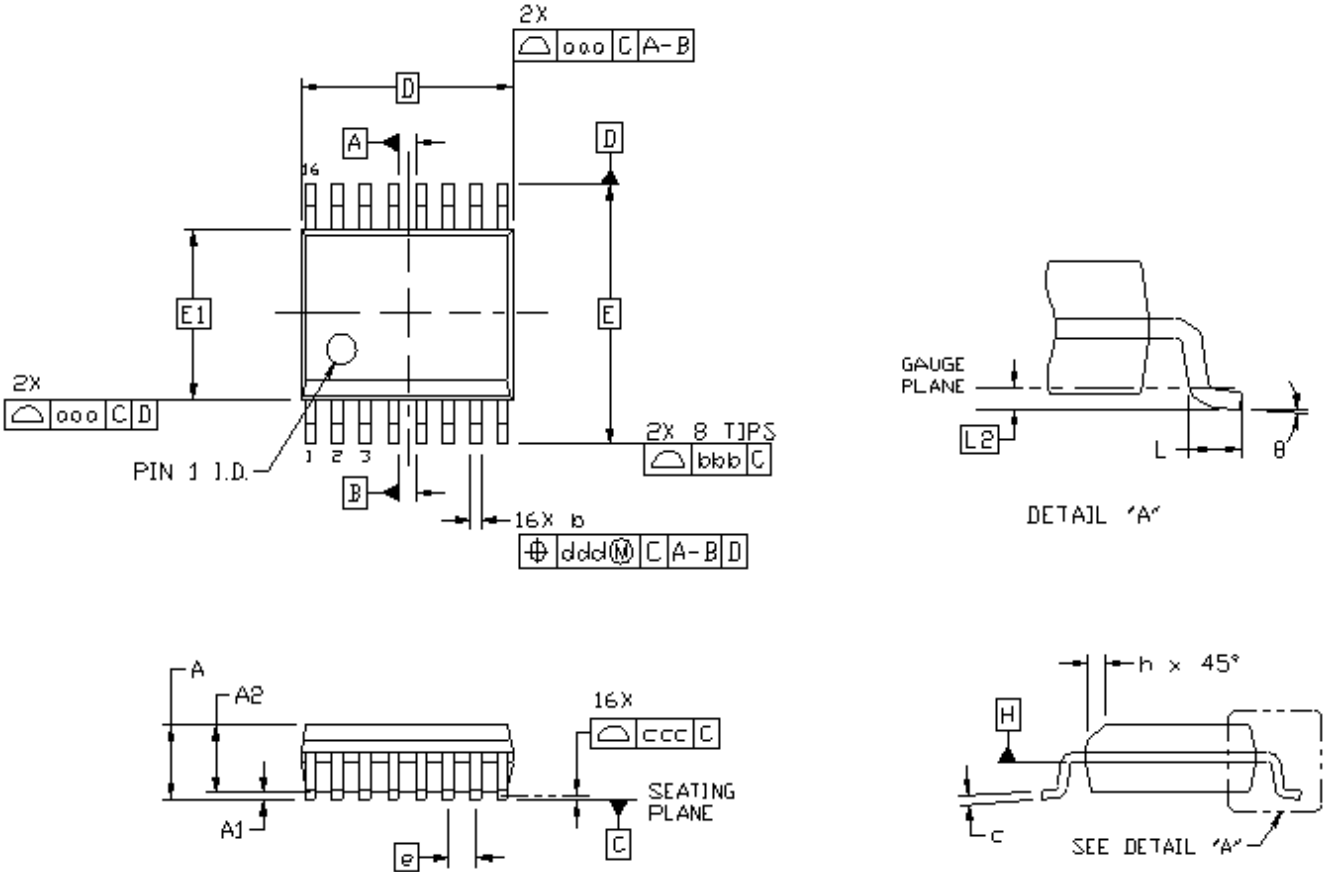


Figure 10.1. 16-Pin QSOP Package

Table 10.1. 16-Pin QSOP Package Diagram Dimensions

| Dimension | Min       | Max  |
|-----------|-----------|------|
| A         | —         | 1.75 |
| A1        | 0.10      | 0.25 |
| A2        | 1.25      | —    |
| b         | 0.20      | 0.30 |
| c         | 0.17      | 0.25 |
| D         | 4.89 BSC  |      |
| E         | 6.00 BSC  |      |
| E1        | 3.90 BSC  |      |
| e         | 0.635 BSC |      |
| L         | 0.40      | 1.27 |
| L2        | 0.25 BSC  |      |
| h         | 0.25      | 0.50 |
| θ         | 0°        | 8°   |
| aaa       | 0.10      |      |
| bbb       | 0.20      |      |
| ccc       | 0.10      |      |
| ddd       | 0.25      |      |

**Notes:**

1. All dimensions shown are in millimeters (mm) unless otherwise noted.
2. Dimensioning and Tolerancing per ANSI Y14.5M-1994.
3. This drawing conforms to the JEDEC Solid State Outline MO-137, Variation AB.
4. Recommended card reflow profile is per the JEDEC/IPC J-STD-020 specification for Small Body Components.

### 11. Land Pattern (16-Pin QSOP)

The figure below illustrates the recommended land pattern details for the Si86xx in a 16-pin QSOP package. The table below lists the values for the dimensions shown in the illustration.

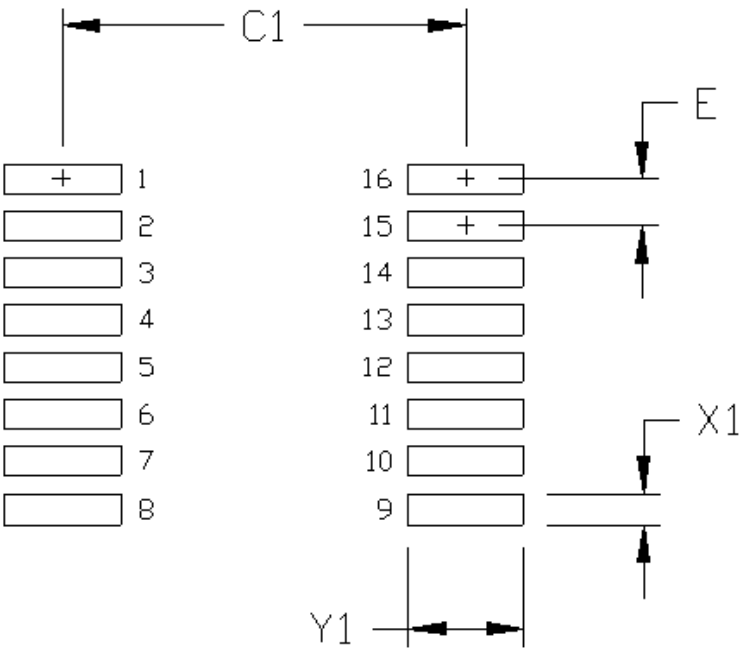


Figure 11.1. 16-Pin QSOP PCB Land Pattern

Table 11.1. 16-Pin QSOP Land Pattern Dimensions

| Dimension | Feature            | (mm)  |
|-----------|--------------------|-------|
| C1        | Pad Column Spacing | 5.40  |
| E         | Pad Row Pitch      | 0.635 |
| X1        | Pad Width          | 0.40  |
| Y1        | Pad Length         | 1.55  |

**Notes:**

1. This Land Pattern Design is based on IPC-7351 pattern SOP63P602X173-16N for Density Level B (Median Land Protrusion).
2. All feature sizes shown are at Maximum Material Condition (MMC) and a card fabrication tolerance of 0.05 mm is assumed.

## 12. Top Marking (16-Pin Wide Body SOIC)

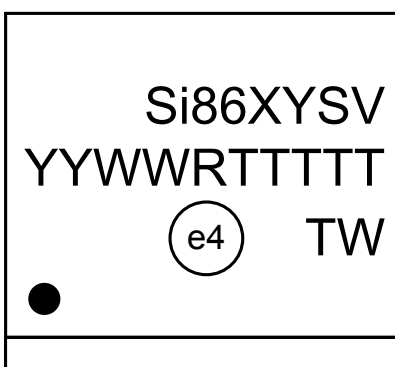


Figure 12.1. 16-Pin Wide Body SOIC Top Marking

Table 12.1. 16-Pin Wide Body SOIC Top Marking Explanation

|                                                   |                                                                                   |                                                                                                                                                                                                                                                                                                                                                                                                         |
|---------------------------------------------------|-----------------------------------------------------------------------------------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| <b>Line 1 Marking:</b>                            | Base Part Number                                                                  | Si86 = Isolator product series                                                                                                                                                                                                                                                                                                                                                                          |
|                                                   | Ordering Options<br>(See <a href="#">1. Ordering Guide</a> for more information). | XY = Channel Configuration<br>X = # of data channels (5)<br>Y = # of reverse channels (2, 1, 0) <sup>1</sup><br>S = Speed Grade (max data rate) and operating mode:<br>A = 1 Mbps (default output = low)<br>B = 150 Mbps (default output = low)<br>D = 1 Mbps (default output = high)<br>E = 150 Mbps (default output = high)<br>V = Insulation rating<br>A = 1 kV; B = 2.5 kV; C = 3.75 kV; D = 5.0 kV |
| <b>Line 2 Marking:</b>                            | YY = Year                                                                         | Assigned by assembly subcontractor. Corresponds to the year and work week of the mold date.                                                                                                                                                                                                                                                                                                             |
|                                                   | WW = Workweek                                                                     |                                                                                                                                                                                                                                                                                                                                                                                                         |
| <b>Line 3 Marking:</b>                            | RTTTTT = Mfg Code                                                                 | Manufacturing code from assembly house<br>"R" indicates revision                                                                                                                                                                                                                                                                                                                                        |
|                                                   | Circle = 1.7 mm Diameter<br>(Center-Justified)                                    | "e4" Pb-free symbol                                                                                                                                                                                                                                                                                                                                                                                     |
|                                                   | Country of Origin ISO Code Abbreviation                                           | TW = Taiwan as shown, TH = Thailand                                                                                                                                                                                                                                                                                                                                                                     |
| <b>Note:</b><br>1. Si8655 has 0 reverse channels. |                                                                                   |                                                                                                                                                                                                                                                                                                                                                                                                         |

### 13. Top Marking (16-Pin Narrow Body SOIC)

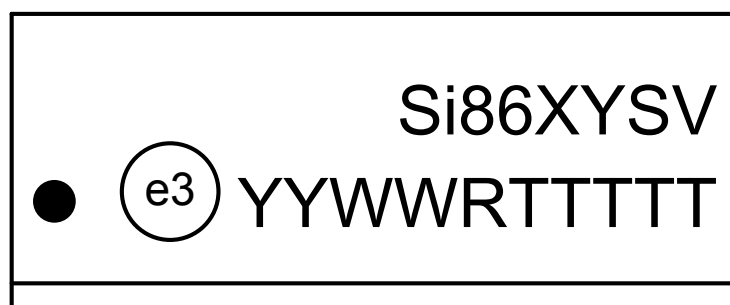


Figure 13.1. 16-Pin Narrow Body SOIC Top Marking

Table 13.1. 16-Pin Narrow Body SOIC Top Marking Explanation

|                                                   |                                                                                   |                                                                                                                                                                                                                                                                                                                                                                                                                                                                              |
|---------------------------------------------------|-----------------------------------------------------------------------------------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| <b>Line 1 Marking:</b>                            | Base Part Number                                                                  | <p>Si86 = Isolator product series</p> <p>XY = Channel Configuration</p> <p>X = # of data channels (5)</p> <p>Y = # of reverse channels (2, 1, 0) <sup>1</sup></p> <p>S = Speed Grade (max data rate) and operating mode:</p> <p>A = 1 Mbps (default output = low)</p> <p>B = 150 Mbps (default output = low)</p> <p>D = 1 Mbps (default output = high)</p> <p>E = 150 Mbps (default output = high)</p> <p>V = Insulation rating</p> <p>A = 1 kV; B = 2.5 kV; C = 3.75 kV</p> |
|                                                   | Ordering Options<br>(See <a href="#">1. Ordering Guide</a> for more information). |                                                                                                                                                                                                                                                                                                                                                                                                                                                                              |
|                                                   |                                                                                   |                                                                                                                                                                                                                                                                                                                                                                                                                                                                              |
| <b>Line 2 Marking:</b>                            | Circle = 1.2 mm Diameter                                                          | "e3" Pb-Free Symbol                                                                                                                                                                                                                                                                                                                                                                                                                                                          |
|                                                   | YY = Year                                                                         | Assigned by the assembly subcontractor. Corresponds to the year and work week of the mold date.                                                                                                                                                                                                                                                                                                                                                                              |
|                                                   | WW = Work Week                                                                    |                                                                                                                                                                                                                                                                                                                                                                                                                                                                              |
|                                                   | RTTTTT = Mfg Code                                                                 | <p>Manufacturing code from assembly house.</p> <p>"R" indicates revision.</p>                                                                                                                                                                                                                                                                                                                                                                                                |
| <b>Note:</b><br>1. Si8655 has 0 reverse channels. |                                                                                   |                                                                                                                                                                                                                                                                                                                                                                                                                                                                              |

## 14. Top Marking (16-Pin QSOP)

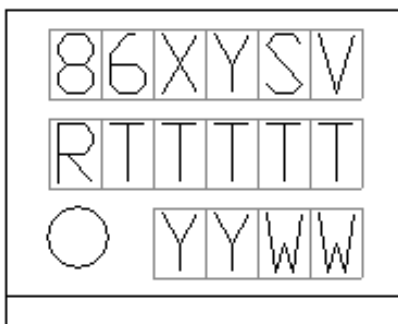


Figure 14.1. 16-Pin QSOP Top Marking

Table 14.1. 16-Pin QSOP Top Marking Explanation

|                                                   |                                                                                                       |                                                                                                                                                                                                                                                                                                                                                                                                                              |
|---------------------------------------------------|-------------------------------------------------------------------------------------------------------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| <b>Line 1 Marking:</b>                            | Base Part Number<br>Ordering Options<br>(See <a href="#">1. Ordering Guide</a> for more information). | 86 = Isolator product series<br>XY = Channel Configuration<br>X = # of data channels (5)<br>Y = # of reverse channels (2, 1, 0) <sup>1</sup><br>S = Speed Grade (max data rate) and operating mode:<br>A = 1 Mbps (default output = low)<br>B = 150 Mbps (default output = low)<br>D = 1 Mbps (default output = high)<br>E = 150 Mbps (default output = high)<br>V = Insulation rating.<br>A = 1 kV; B = 2.5 kV; C = 3.75 kV |
| <b>Line 2 Marking:</b>                            | RTTTTT = Mfg Code                                                                                     | Manufacturing code from assembly house.<br>“R” indicates revision.                                                                                                                                                                                                                                                                                                                                                           |
| <b>Line 3 Marking:</b>                            | YY = Year<br>WW = Work Week                                                                           | Assigned by the Assembly House. Corresponds to the year and work week of the mold date.                                                                                                                                                                                                                                                                                                                                      |
| <b>Note:</b><br>1. Si8655 has 0 reverse channels. |                                                                                                       |                                                                                                                                                                                                                                                                                                                                                                                                                              |

## 15. Revision History

### Revision 2.01

January 2018

- Added new table to Ordering Guide for Automotive-Grade OPN options.

### Revision 2.0

October 18, 2017

- Added new OPNs in Ordering Guide for IU (QSOP) and IS2 (8 mm creepage WB SOIC) package options.
- Added 62368-1 references throughout.
- Removed 61010-1 references throughout.

### Revision 1.9

November 30, 2016

- Updated data sheet format.
- Added note to [Table 1.1 Ordering Guide for Valid OPNs<sup>1, 2, 3</sup>](#) on page 2 for denoting tape and reel marking.

### Revision 1.8

June 18, 2015

- Updated [Table 4.5 Regulatory Information<sup>1</sup>](#) on page 21.
  - Added CQC certificate numbers.
- Updated [1. Ordering Guide](#).
  - Removed references to moisture sensitivity levels.
  - Removed former note 2.

### Revision 1.7

September 25, 2013

- Added [Figure 4.3 Common Mode Transient Immunity Test Circuit](#) on page 15.
- Added references to CQC throughout.
- Added references to 2.5 kV<sub>RMS</sub> devices throughout.
- Updated [1. Ordering Guide](#).
- Updated [12. Top Marking \(16-Pin Wide Body SOIC\)](#).
- Updated [14. Top Marking \(16-Pin QSOP\)](#).

### Revision 1.6

June 26, 2012

- Added junction temperature spec to [Table 4.11 Absolute Maximum Ratings<sup>1</sup>](#) on page 25.
- Updated [3.3.1 Supply Bypass](#).
- Removed former Section 3.3.2. Pin Connections.
- Updated table notes in [5.1 Si8650/51/52 Pin Descriptions](#).
- Removed Rev A devices from [1. Ordering Guide](#).
- Updated [6. Package Outline \(16-Pin Wide Body SOIC\)](#).
- Added revision description to Top Markings.

### Revision 1.5

March 20, 2012

- Updated [1. Ordering Guide](#) to include MSL2A.



**Revision 1.4**

February 15, 2012

- Updated [Table 1.1 Ordering Guide for Valid OPNs<sup>1, 2, 3</sup>](#) on page 2.
- Updated Note 1 with MSL2A.

**Revision 1.3**

November 11, 2011

- Added Output Current Drive Channel specification for Si865xxA-x-xx devices.
- Added Latchup Immunity specification.

**Revision 1.2**

September 14, 2011

- Updated High Level Output Voltage VOH to 3.1 V in [Table 4.3 Electrical Characteristics](#) on page 16.
- Updated High Level Output Voltage VOH to 2.3 V in [Table 4.4 Electrical Characteristics](#) on page 18.

**Revision 1.1**

July 14, 2011

- Reordered spec tables to conform to new convention.
- Removed "pending" throughout document.

**Revision 1.0**

March 31, 2011

- Added chip graphics on the front page.
- Moved [Table 4.1 Recommended Operating Conditions](#) on page 12 and [Table 4.11 Absolute Maximum Ratings<sup>1</sup>](#) on page 25.
- Updated [4. Electrical Specifications](#).
- Moved [Table 3.1 Si865x Logic Operation](#) on page 7 and [Table 3.2 Enable Input Truth<sup>1</sup>](#) on page 8.
- Moved [3.5 Typical Performance Characteristics](#).
- Updated [5.1 Si8650/51/52 Pin Descriptions](#).
- Updated [5.2 Si8655 Pin Descriptions](#).
- Updated [1. Ordering Guide](#).

**Revision 0.2**

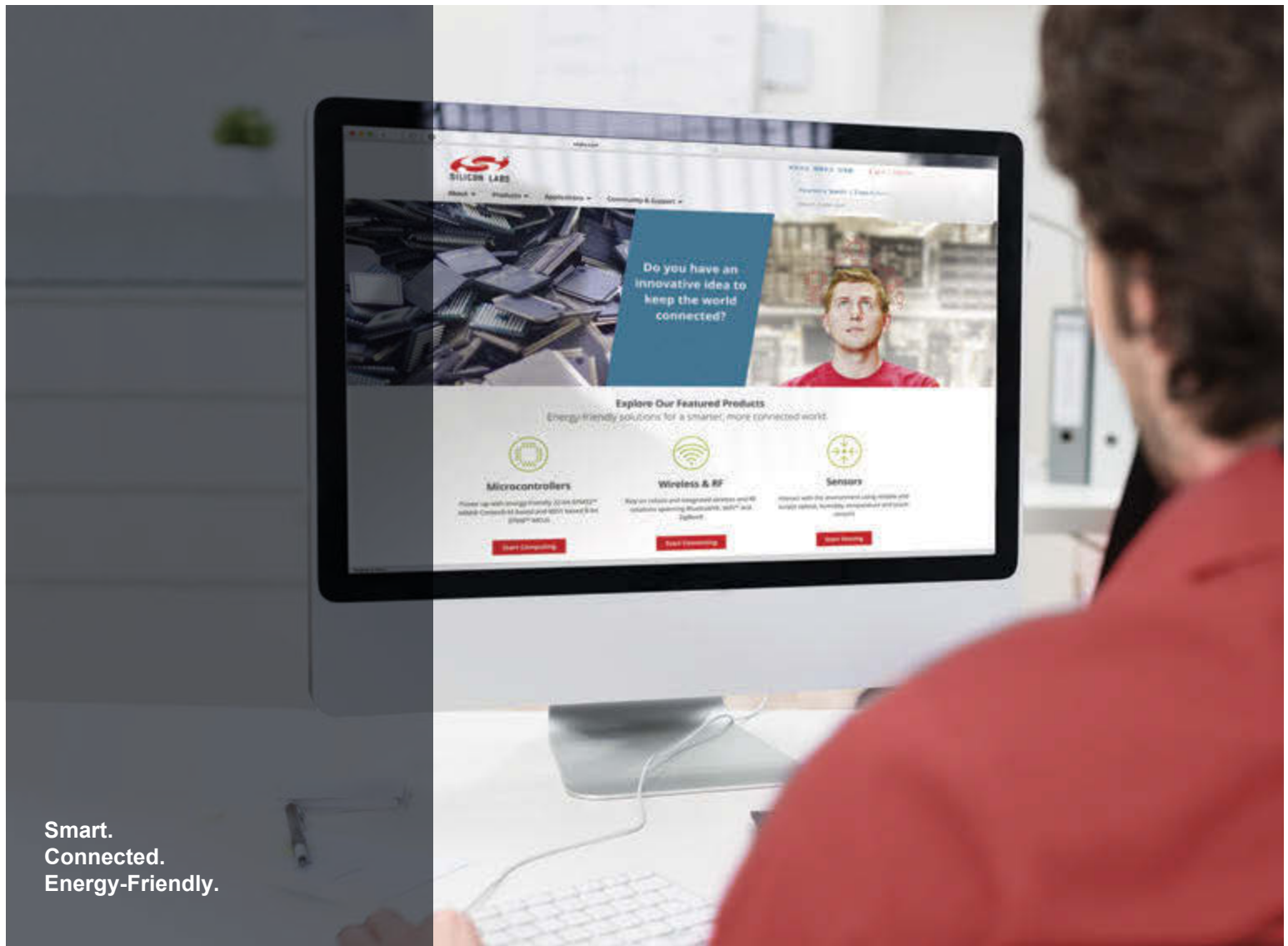
September 15, 2010

- Deleted Sections 4.3.4 and 4.3.5.
- Updated [1. Ordering Guide](#).
  - Updated [Table 1.1 Ordering Guide for Valid OPNs<sup>1, 2, 3</sup>](#) on page 2.
- Added [3.4 Fail-Safe Operating Mode](#).

**Revision 0.1**

June 30, 2010

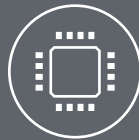
- Initial release.



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